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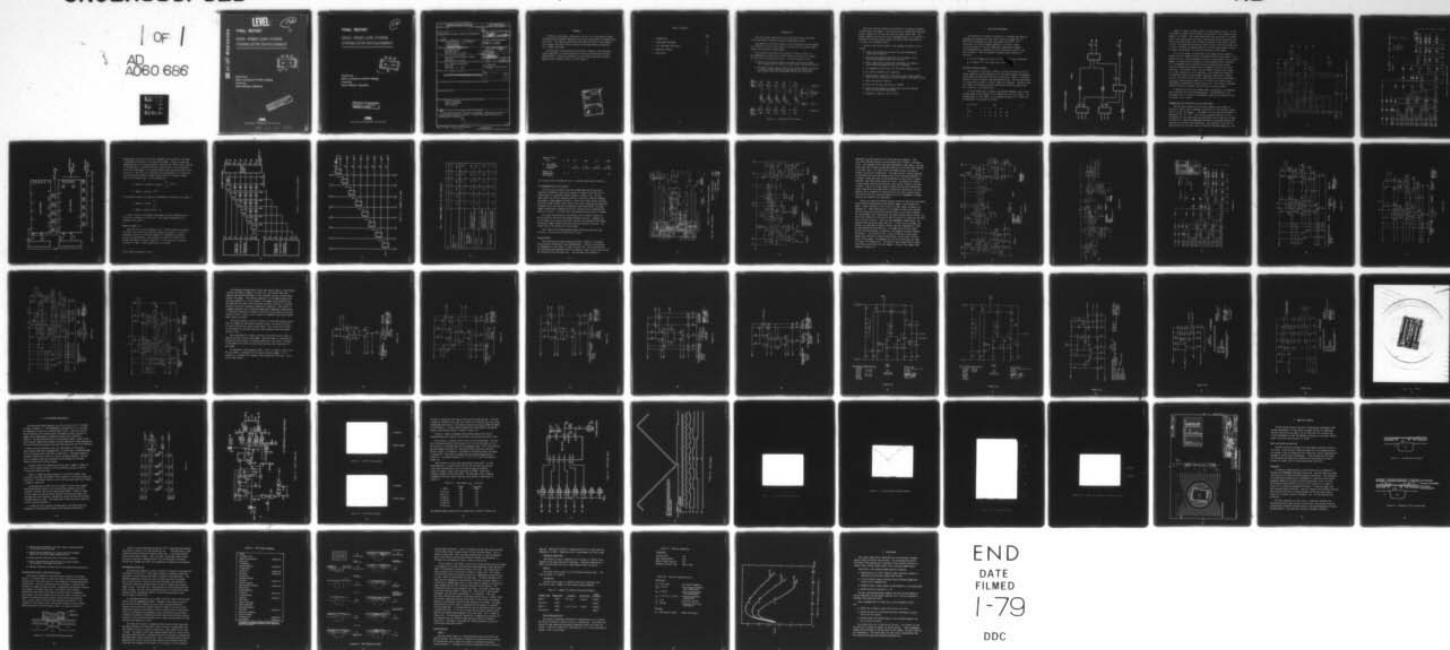
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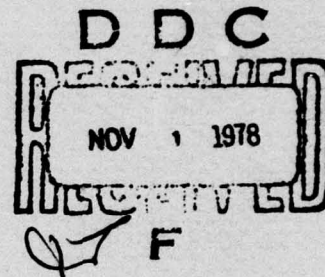
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## FINAL REPORT

# HIGH - SPEED LOW - POWER CORRELATOR DEVELOPMENT



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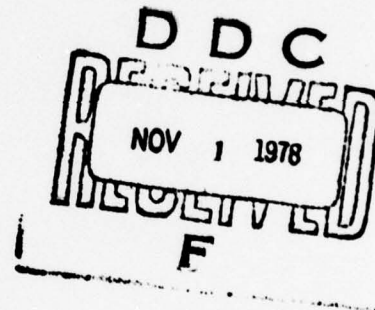
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# FINAL REPORT

## HIGH - SPEED LOW - POWER CORRELATOR DEVELOPMENT

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## FOREWORD

The design, development, fabrication, and test of a high-speed low-power correlator was performed by TRW Defense and Space Systems Group in Redondo Beach, California. This work was sponsored by the Naval Electronics System Command (L.W. Sumney, Code 3042) and was directed by the Naval Research Laboratory (D. F. Barbe, Code 5260).

The principal investigator was David Breuer, Manager of the High Speed Bipolar Department in the Microelectronics Center of TRW Defense and Space Systems Group. Principal contributors to this project were Albert Cosand, Wayne Current, Diogenes Cordero, and Alan Templin.

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## 1. INTRODUCTION

This final report describes the work done during the fourth phase of the High-Speed, Low-Power Correlator Development program.

The objective of the fourth phase of this program was the development of a monolithic 32-bit digital parallel correlator with an analog summed output, and a digitally summed output.

The correlator functional block diagram is shown in Figure 1-1. Two independently clocked 32-bit shift registers (A and B) are compared bit by bit by 32 exclusive-OR circuits. Each exclusive-OR circuit:

- Controls a D/A current source; the output currents are summed into a common node to produce an analog output correlation function.
- Provides a digital signal to the 32-bit digital summer; the output is a binary-coded digital word representing the sum of digits which agree at any one time between the two shift registers.

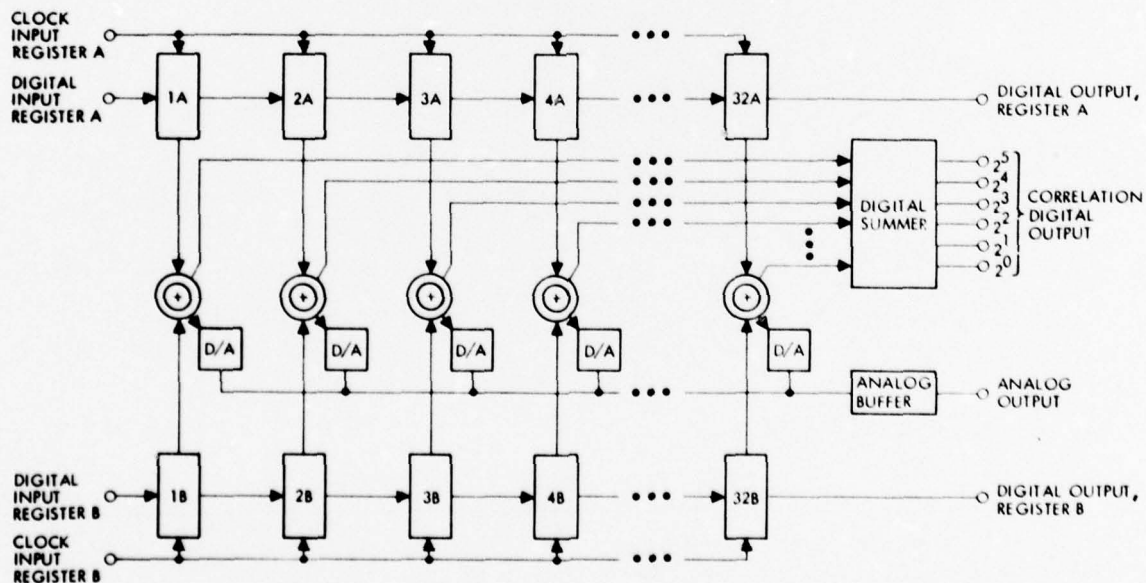


Figure 1-1. Correlator Block Diagram

Both shift register outputs are available for cascading LSI modules to form longer word lengths. The correlator will provide both analog and digital outputs; the user has the choice of either signal form. The digital summing circuit will receive independent power, so if the user is interested in only the analog output, the power of the unused digital circuitry can be reduced to zero.

The basic specification goals of the proposed correlator circuit include:

- Signal and reference data entered into two independently clocked shift registers.
- Analog current output proportional to the number of bits correlating between the two shift registers.
- Binary coded digital output which represents the number of bits correlating between the two shift registers.
- An independent clock control on the digital summing circuit.
- All digital interfaces ECL compatible.
- Analog output current of 0.2 mA per bit, plus offset current, with bit-to-bit accuracies  $\leq 5\%$  with respect to the nominal value.
- Power dissipation of 480 mW.
- Clock rate of each clock input of 150 MHz.
- Digital output appears not longer than five clock periods after the correlation measurement.
- Temperature range of  $-55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ .



## 2. CORRELATOR DEVELOPMENT

The function of the digital correlator is to compute the number of agreement bits between two binary words (usually of length  $2^N - 1$ ). When  $2^n$ -bit correlators are used, the outputs from  $2^N/2^n = 2^{N-n}$  correlators will then be summed together as the overall output. In each correlator,  $2^n$  exclusive-NOR gates (comparators) compare the corresponding bits between two  $2^n$ -bit binary words stored in the shift registers. Here the problem of summing can be looked at in two modes:

- To sum  $2^n$  binary bits into a  $(n+1)$ -bit word inside a correlator.
- To combine  $2^{N-n}$   $n$ -bit words into a  $(N+1)$ -bit word.

### Correlator Digital Summing

The function of the digital summer is to sense the states of the  $2^n$  binary comparators and to generate a  $(n+1)$ -bit binary number corresponding to the number of comparators which are in the logic 1 states. A pipeline approach is used to achieve a maximum operating rate. The pipeline summing is illustrated in Figure 2-1 using 7 inputs as an example. Latched 3-input full adders are the basic building block which allows the summing rate only limited by a full adder delay.

It can be shown that, in general, the optimal summing circuit (using minimum number of full adders) is to compute the sum of  $2^n - 1$  inputs. The minimum number of full adders,  $S_n$ , to compute the sum of  $2^n - 1$  inputs can be expressed in an equation as follows:

$S_n = 2^n - 1 - n$	for						$n > 2$
$n$	2	3	4	5	6	7	...
$2^n - 1$	3	7	15	31	63	127	...
$S_n$	1	4	11	26	57	120	...



Figure 2-2 shows an optimal digital 31-input summing circuit. It uses 26 latched full adders and 16 latches, and provides a 5-bit "skewed" binary number as its output. The skewed output means that the output is available after 5 clock periods with the least-significant-bit (LSB) available at the fourth clock period after the 31 inputs are applied to the digital summing circuit, the second LSB available at the end of the fifth clock period, and so forth. Providing the skewed output will simplify the hardware required to expand the correlator for processing of words of long lengths.

For a 32-bit summer, an additional 5 half adders will be needed to expand the 31-bit summing circuit to provide the 6-bit binary output. This add-one circuitry can be implemented on-chip or using external logic circuits. However, to operate the correlator as a self-contained 32-bit correlator, it is recommended that the add-one circuitry should be built on-chip. Figure 2-3 presents the complete digital summing circuit for the 32-bit correlator. The add-one circuit uses full adders instead of half adders at a slight increase to circuit complexity, but provides the capability of combining the 5-bit binary number  $S_1S_2S_3S_4S_5$ , representing a number up to 31, the 32<sup>nd</sup> correlator output, and an external 5-bit binary number  $I_1I_2I_3I_4I_5$ , representing a number up to 31 into a 6-bit binary output,  $T_1T_2T_3T_4T_5T_6$ , representing a maximum count of 63. This allows an implementation of a 63-bit correlator with two 32-bit correlator modules.

In addition to the six bit skewed output,  $T_1T_2T_3T_4T_5T_6$ , a synchronous sum is available on pins  $SS_1SS_2SS_3SS_4SS_5SS_6$ . The availability of the synchronous sum is a matter of convenience, requiring the addition of only 10 latches to the circuit.

#### Implementation for Correlators of Very Long Length

The correlator design with the digital summing circuit shown in Figure 2-3, can be used to implement correlators of very long word length; say  $2^N - 1$  or  $2^N$ , for large N's. The number of 32-bit correlator modules is computed by  $2^N \div 32 = 2^{N-5}$ . For a 63-bit correlator where  $N = 6$ , two correlators will be used without any additional circuits required as shown in Figure 2-4. Here both skewed and synchronous (non-skewed) outputs are available for further signal processing. The synchronous output can be used directly for functions such as correlation threshold detection. The

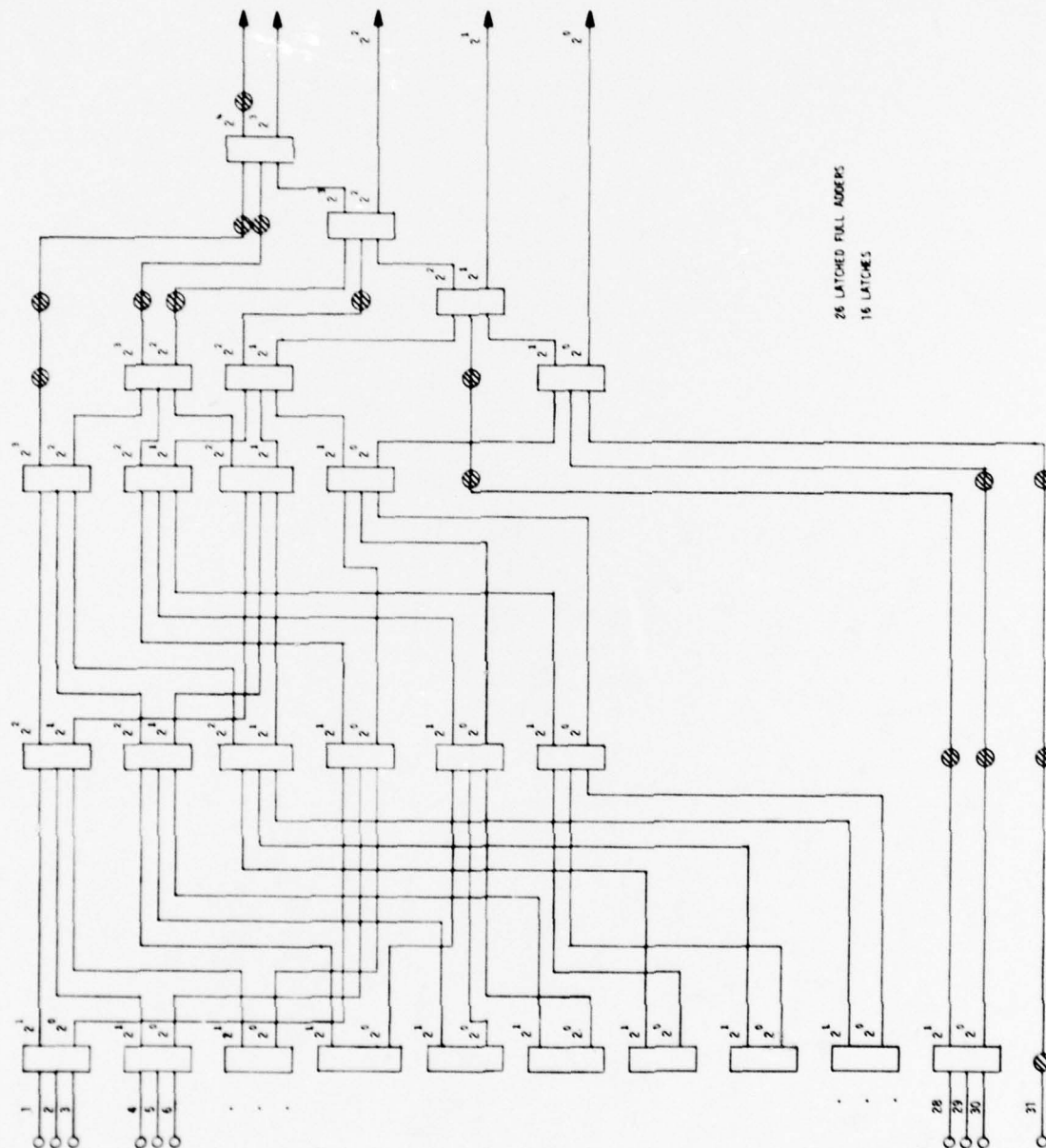


Figure 2-2. A 31-Bit Pipeline Summing Circuit



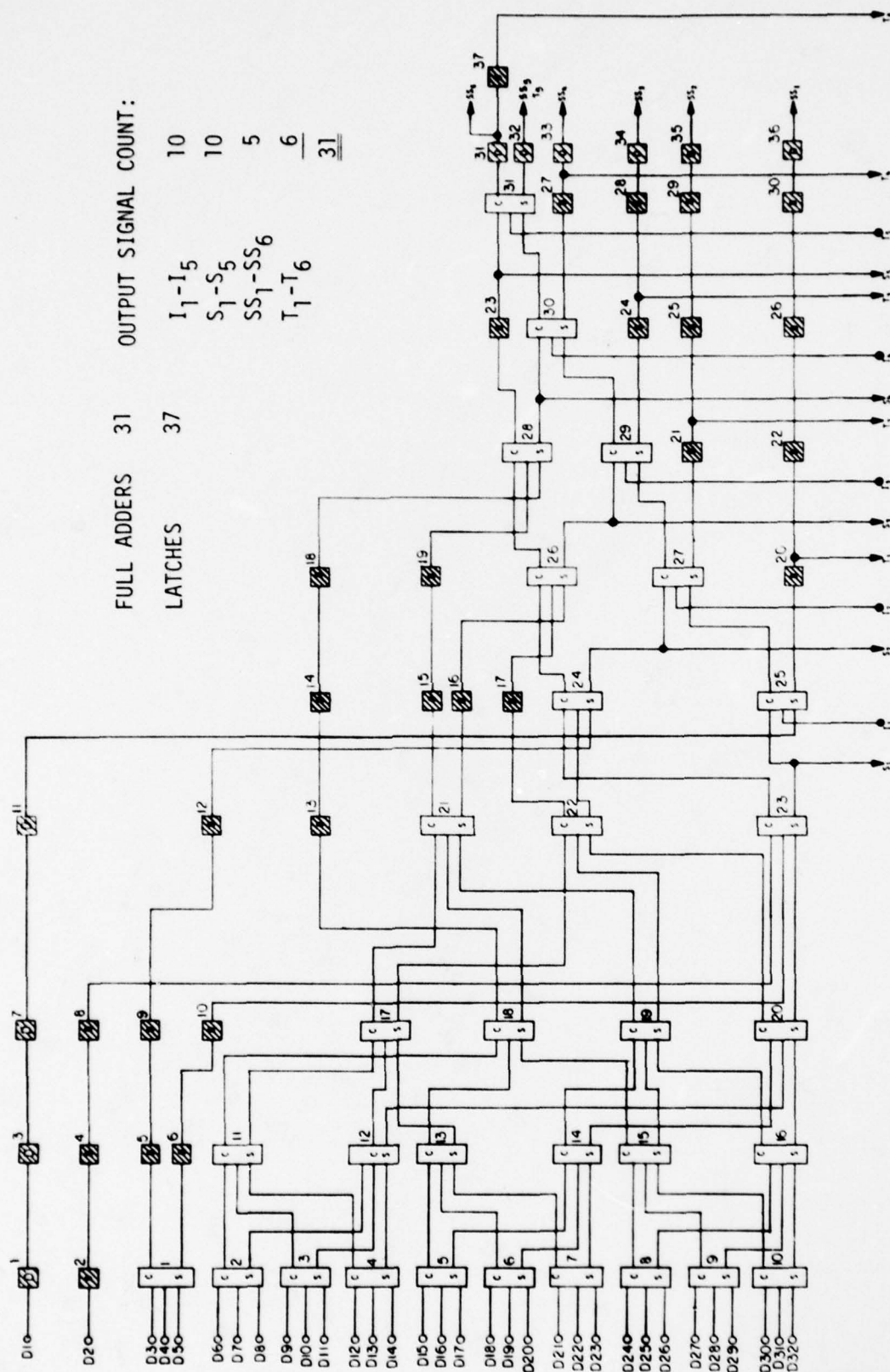


Figure 2-3. Digital Summer 32-D0C

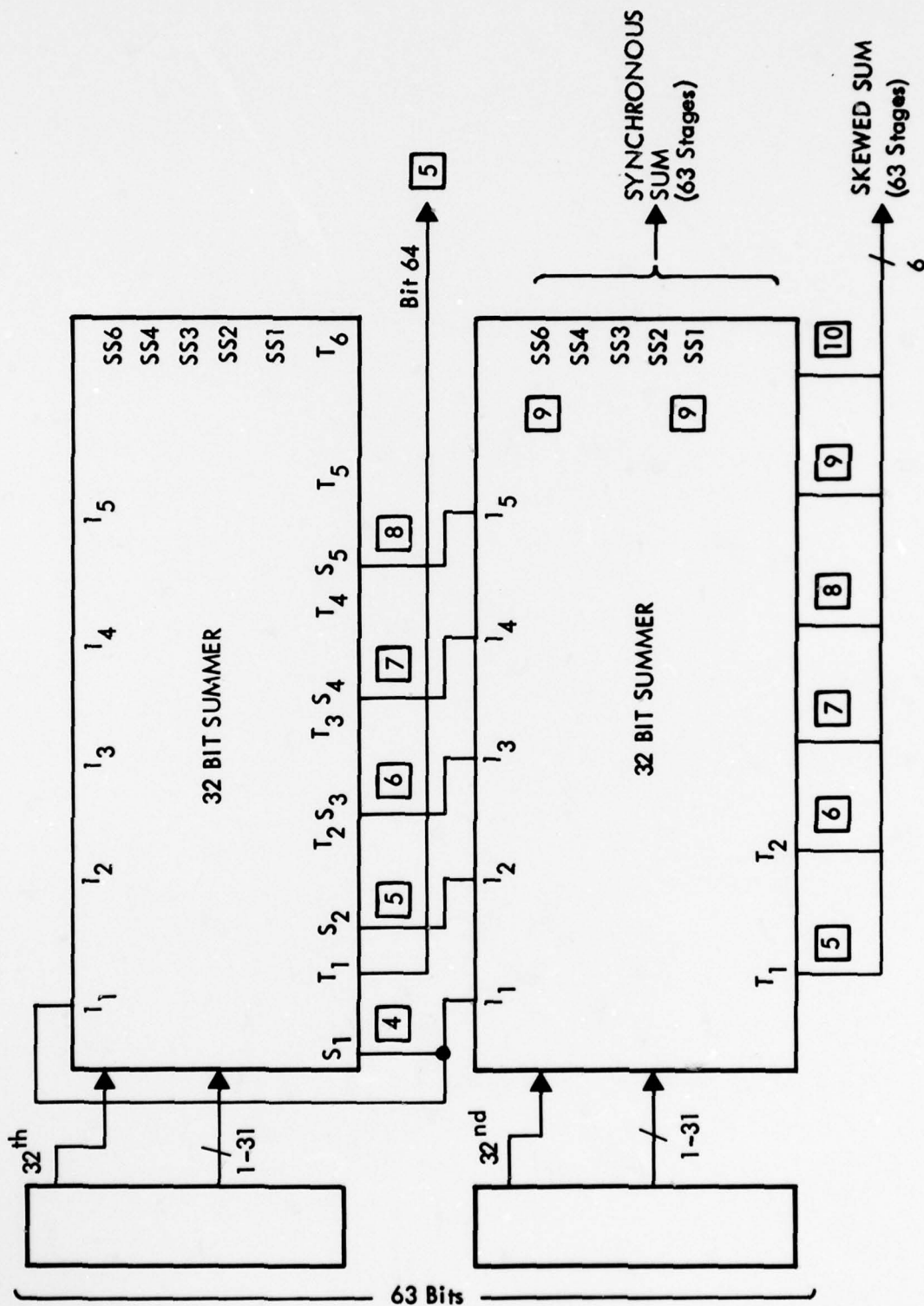


Figure 2-4. Interconnection of Two 32-Bit Summers to Implement a 63-Bit Summer

skewed output can be used for further expanding the 63 (64)-bit correlators to implement correlators of very long word lengths. Figure 2-5 shows the implementation of a 127-bit correlator. Note that the "extra" delay incurred in the generation of the 64<sup>th</sup> correlator output causes it to be available on the clock phase when it is required, which avoids the need to add a latch to delay it. Any  $(2^N-1)$ -bit correlator can be implemented in a similar way and the external hardware to combine the 63 (64)-bit correlator outputs into a N-bit skewed output, can be estimated by:

$$A. \text{ Number of latched full adders*} = \sum_{I=6}^{N-1} 1 \cdot 2^{N-I-1}$$

$$B. \text{ Number of latches} = 2^{N-6} - 1$$

If synchronous outputs are required, the hardware in addition to the above is:

$$C. \text{ Number of latches} = \sum_{J=1}^{N-2} J$$

$$D. \text{ Number of output latches} = N$$

Table 1 presents the hardware requirements for the implementation of  $(2^N-1)$ -bit correlators; for  $n=5$  to 10. This summing technique can be expanded by any large N.

#### Need of a Summer LSI

Note that this external summing circuit is quite repetitive in nature. The overall parts count can be greatly reduced if another LSI circuit is developed to perform the external summing for implementing correlators of very long word lengths. As an example, consider the "skewed" 8-bit latched full adder as shown in Figure 2-6. If this device is available, the item A in Table 1 can be simplified to as follows:

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\*A full adder followed by a latch.

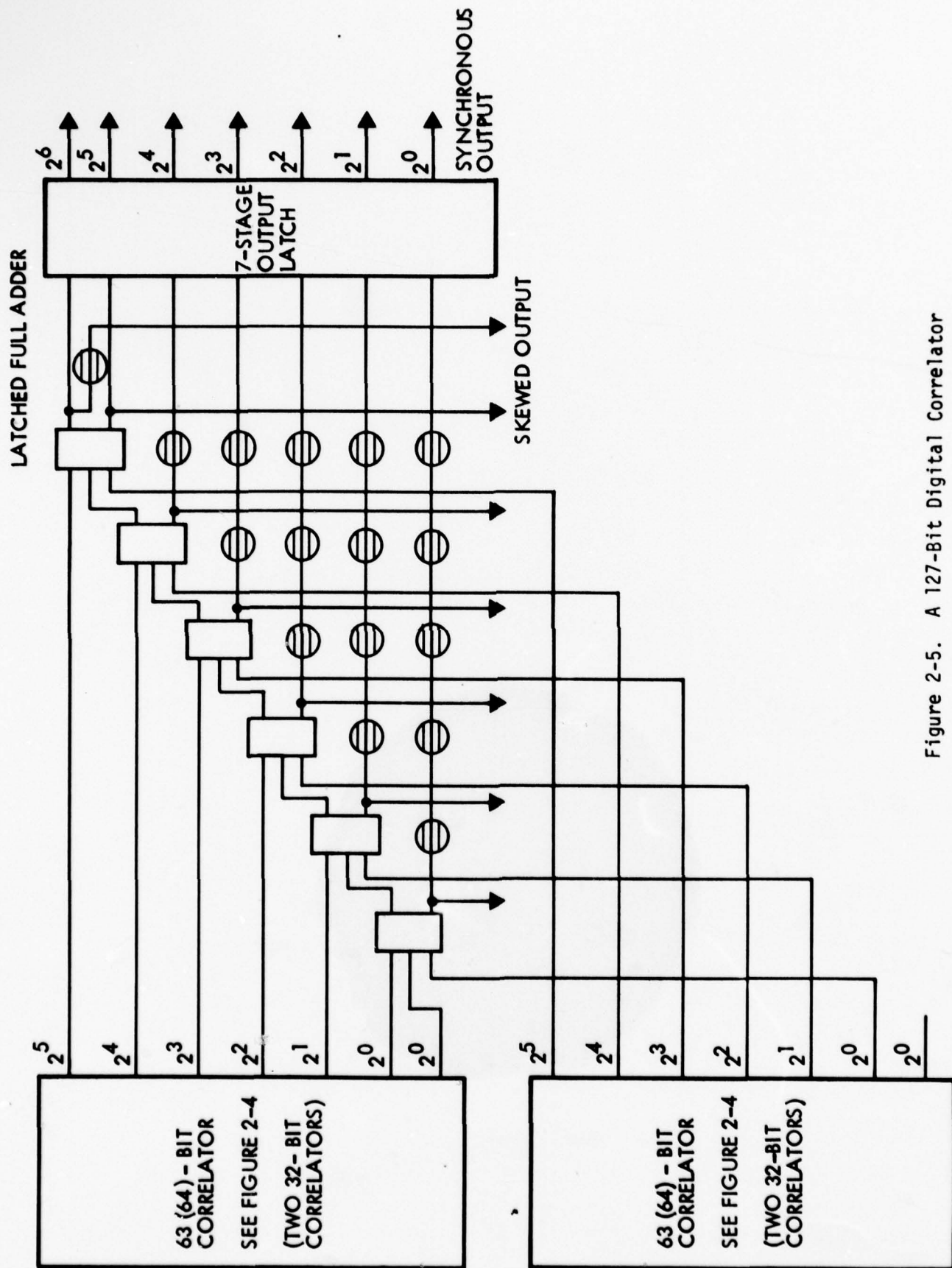


Figure 2-5. A 127-Bit Digital Correlator



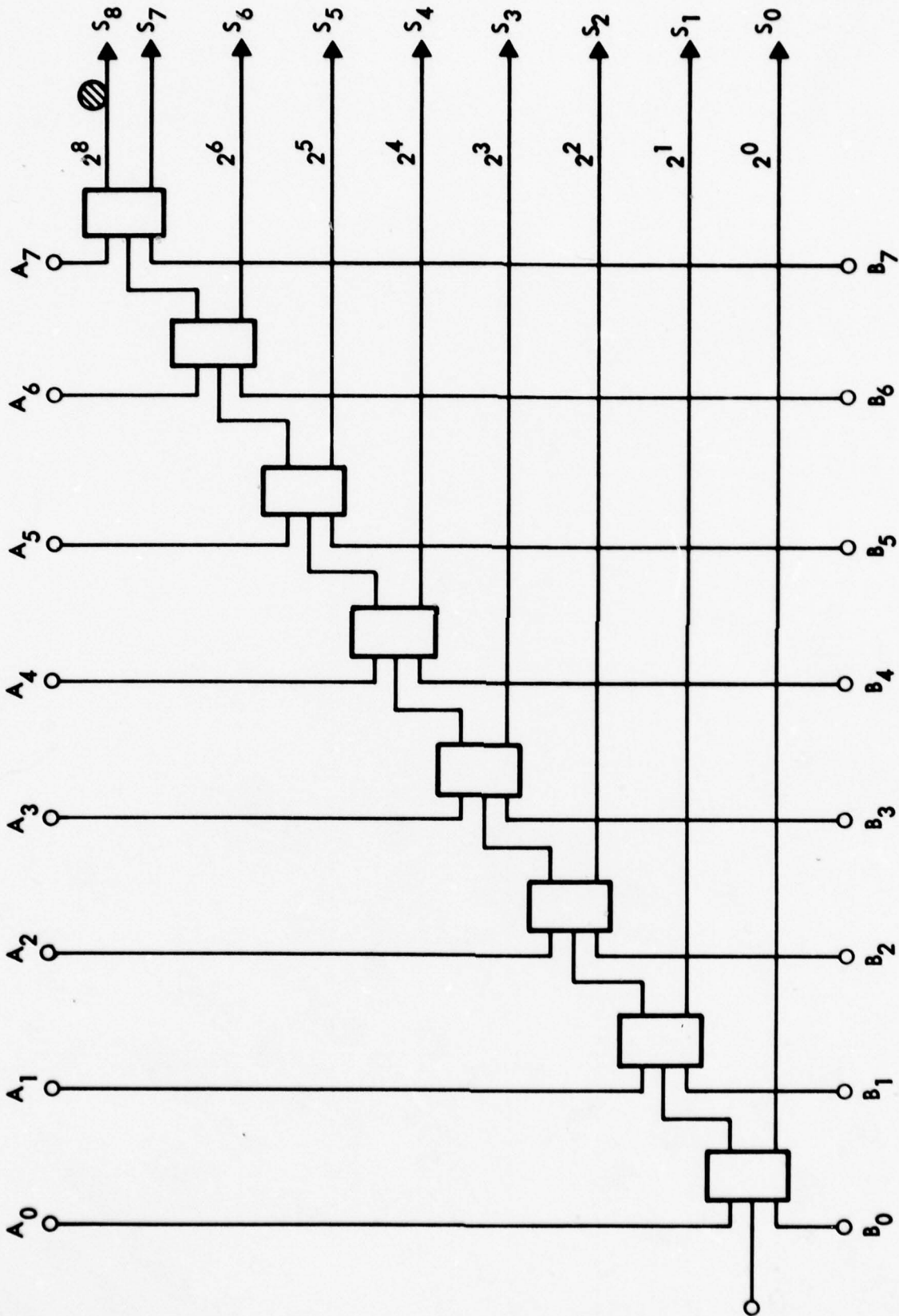


Figure 2-6. A "Skewed" 8-Bit Adder

TABLE 1. HARDWARE SUMMARY OF  $(2^N - 1)$ -BIT CORRELATOR

N		N = 5	N = 6	N = 7	N = 8	N = 9	N = 10
Number of bits ( $2^N - 1$ )		31	63	127	255	511	1023
32-bit Correlators		1	2	4	8	16	32
A. Full Adders (with output latched)	(to sum correlator outputs into a N-bit skewed output)	0	0	6	19	46	101
B. Latches		0	0	1	3	7	15
C. Latches	(to delay the skewed output into a synchronous output)	0	0	15	21	28	36
D. Output Latch	(to store the N-bit synchronous output)	0	0	7	8	9	10

Number of bits = $2^N - 1$	31	63	127	255	511	1,023
A. Full Adders (with outputs latched).	0	0	6 (5 IC's)	19 (15 IC's)	38 (29 IC's)	101 (76 IC's)
Replace by skewed 8-bit full adders	0	0	1	3	7	15

It is obvious that the summing circuit is greatly simplified for large N's.

#### LSI Implementation of the 32-DOC-1

Electrical design options have been implemented which allow either low-level differential signals to be output as signals  $S_1-S_5$  and  $\bar{S}_1-\bar{S}_5$  or single-ended, ECL compatible signals output as signals  $S_1-S_5$ . The  $V_{EE}$  power supply for the ECL compatible option is -6.0 volts, and the estimated chip power is approximately 0.8 watts. Since the S output signals interface only with another 32-DOC-1 chip, the full ECL signal swing may be unnecessary. By making use of the low-level differential logic swing option, the power supply voltage may be reduced to -5.2 volts, resulting in an estimated chip power of 0.7 watts. In either form, the projected clocking rate is 150 MHz.

The layout organization of the 32-DOC-1 chip is shown in Figure 2-7. On the right are the clock and voltage reference circuits. Eighteen bits of correlation are placed on the top of the die, and fourteen on the bottom. The digital summer occupies the center and left portions of the die. The signal flow of the 32-DOC chip is also shown.

The 32-DOC-1 chip contains approximately 3350 transistors and 1120 resistors. The die size is 238 mils by 173 mils.

#### Circuit Design

The thirty-two bit digital output correlator, 32-DOC-1, is designed using low-level differential logic implementation. One bit of correlation, as implemented in the 32-DOC, is shown in Figure 2-8. The shift registers are straightforward implementations of differential logic, except level-shifted for interfacing with the adder tree. The left-hand shift register is





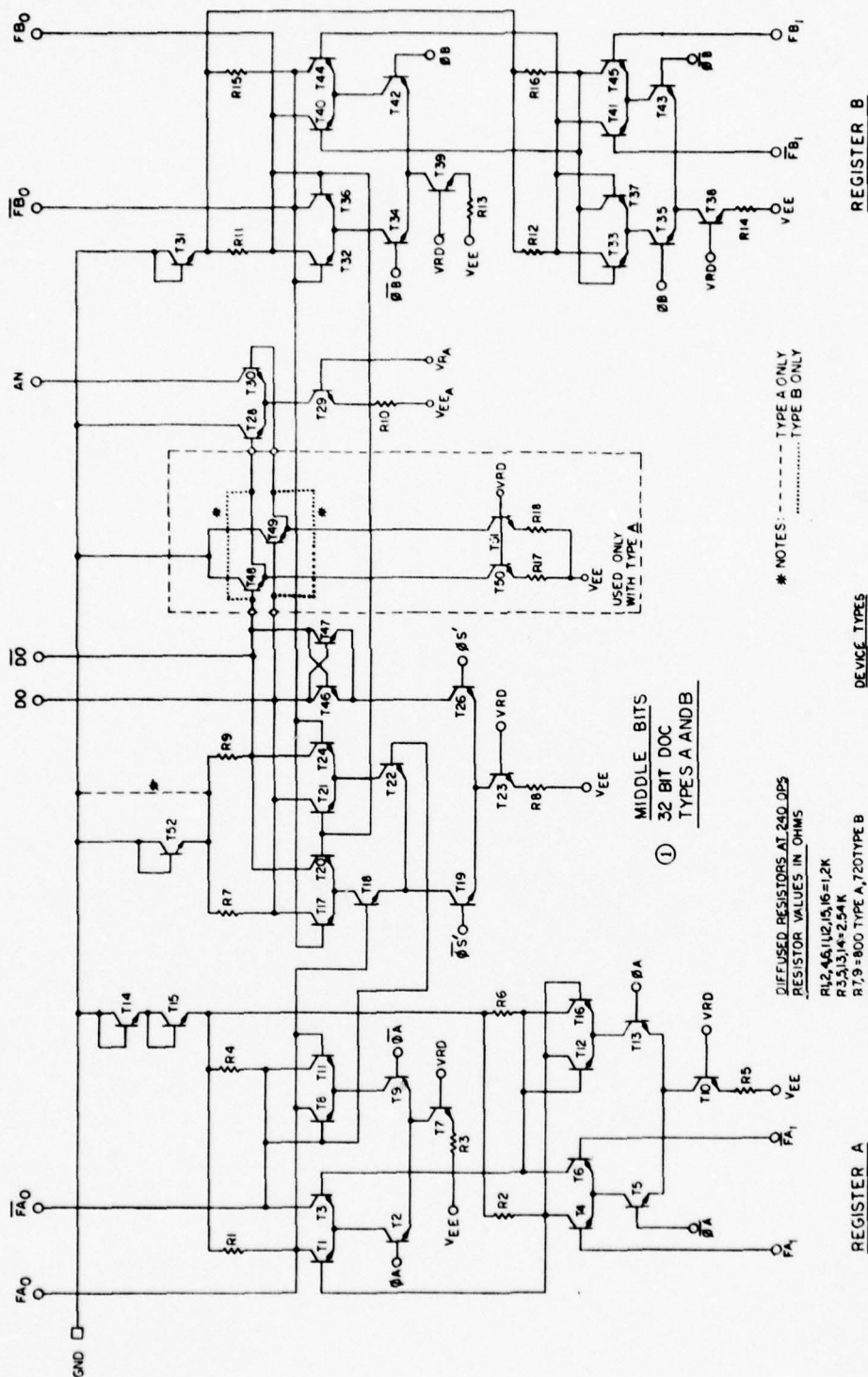
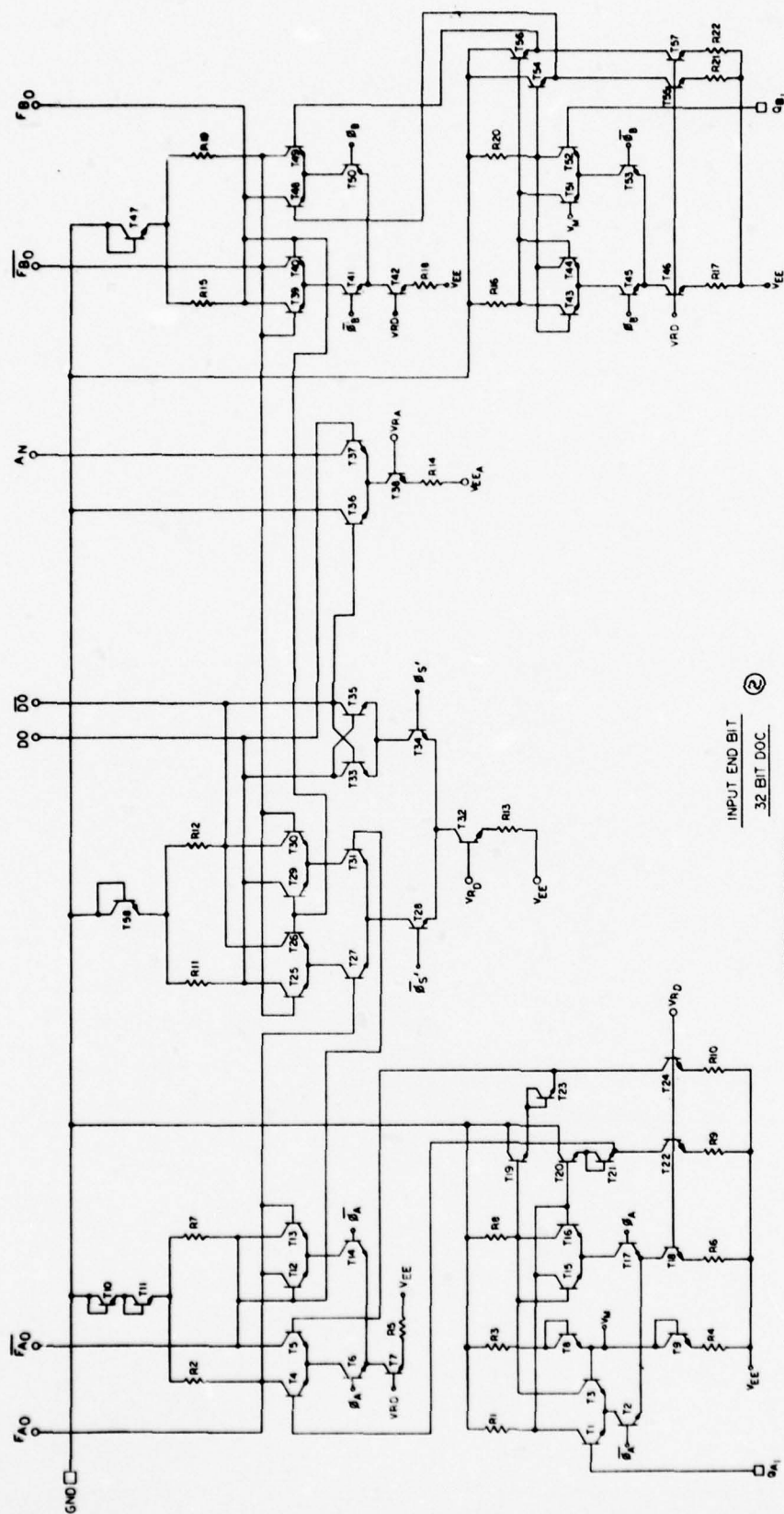


Figure 2-8.

reference  $-V_{BE}$  with respect to the right hand shift register. This facilitates driving the exclusive-OR without level shifters in the data lines. This approach offers high speed performance, lower power, and lower parts count than the more conventional approach of utilizing level-shifters in the data lines. The input end-bit and output end-bit are shown in Figures 2-9 and 2-10, respectively. The input end bit is nearly identical to the middle bits with the exception that an ECL threshold generator is included, so that the input bit can accept data in the form of a single-ended ECL input signal with normal ECL levels. The output bit contains a single master latch and two parallel slave latches in both of the data registers. One of the slave latches provides the low level differential signal required by the exclusive-OR to perform the correlation; the other operates with a standard ECL swing and drives the shift register output. This ensures that the correlation operation will be independent of output loading, and simplifies the correlator.

Figure 2-11 shows the complete summing circuit for the 32-bit correlator. The principal building block of the digital summer is the latched full adder. Several versions of this circuit are used, shown in Figures 2-12 through 2-15. These differ mainly in the number of input level shifters that are required to interface to the particular set of inputs supplied to a given adder, and in the options for output voltage swing in Figure 2-14. The circuit operation is most easily seen in Figure 2-12, which has the least level shifting circuitry. There are two independent latched gates; one generates the sum and the other the carry. In the circuit as drawn, the latches are configured as master latches; they may be operated as slaves by interchanging the  $\emptyset$  and  $\bar{\emptyset}$  lines. The summer also utilizes simple latches to provide delays as required in the summing tree and to deskew the outputs. Five versions of the latches, differing in input and/or output level shifting or output voltage swing, are utilized in various places in the summer. The schematics of the five latch types are shown in Figures 2-16 through 2-20. The specific type of adder-latch or delay latch used at each position in the summer is listed in the summer block diagram of Figure 2-11.



REGISTER B

DEVICE TYPES  
TIL2

INPUT ENO BIT  
32 BIT DOC

RESISTOR VALUES IN OHMS  
R1,2,3,4,5,6,7,8,9,10,11,12,13,14,15,16,17,18,19,20,21,22,23,24,25,26,27,28,29,30,31,32,33,34,35,36,37,38,39,40,41,42,43,44,45,46,47,48,49,50,51,52,53,54,55,56,57,58,59,60,61,62,63,64,65,66,67,68,69,70,71,72,73,74,75,76,77,78,79,80,81,82,83,84,85,86,87,88,89,90,91,92,93,94,95,96,97,98,99,100,101,102,103,104,105,106,107,108,109,110,111,112,113,114,115,116,117,118,119,120,121,122,123,124,125,126,127,128,129,130,131,132,133,134,135,136,137,138,139,140,141,142,143,144,145,146,147,148,149,150,151,152,153,154,155,156,157,158,159,160,161,162,163,164,165,166,167,168,169,170,171,172,173,174,175,176,177,178,179,180,181,182,183,184,185,186,187,188,189,190,191,192,193,194,195,196,197,198,199,200,201,202,203,204,205,206,207,208,209,210,211,212,213,214,215,216,217,218,219,220,221,222,223,224,225,226,227,228,229,230,231,232,233,234,235,236,237,238,239,240,241,242,243,244,245,246,247,248,249,250,251,252,253,254,255,256,257,258,259,260,261,262,263,264,265,266,267,268,269,270,271,272,273,274,275,276,277,278,279,280,281,282,283,284,285,286,287,288,289,290,291,292,293,294,295,296,297,298,299,300,301,302,303,304,305,306,307,308,309,310,311,312,313,314,315,316,317,318,319,320,321,322,323,324,325,326,327,328,329,330,331,332,333,334,335,336,337,338,339,340,341,342,343,344,345,346,347,348,349,350,351,352,353,354,355,356,357,358,359,360,361,362,363,364,365,366,367,368,369,370,371,372,373,374,375,376,377,378,379,380,381,382,383,384,385,386,387,388,389,390,391,392,393,394,395,396,397,398,399,400,401,402,403,404,405,406,407,408,409,410,411,412,413,414,415,416,417,418,419,420,421,422,423,424,425,426,427,428,429,430,431,432,433,434,435,436,437,438,439,440,441,442,443,444,445,446,447,448,449,450,451,452,453,454,455,456,457,458,459,460,461,462,463,464,465,466,467,468,469,470,471,472,473,474,475,476,477,478,479,480,481,482,483,484,485,486,487,488,489,490,491,492,493,494,495,496,497,498,499,500,501,502,503,504,505,506,507,508,509,510,511,512,513,514,515,516,517,518,519,520,521,522,523,524,525,526,527,528,529,530,531,532,533,534,535,536,537,538,539,540,541,542,543,544,545,546,547,548,549,550,551,552,553,554,555,556,557,558,559,560,561,562,563,564,565,566,567,568,569,570,571,572,573,574,575,576,577,578,579,580,581,582,583,584,585,586,587,588,589,590,591,592,593,594,595,596,597,598,599,600,601,602,603,604,605,606,607,608,609,610,611,612,613,614,615,616,617,618,619,620,621,622,623,624,625,626,627,628,629,630,631,632,633,634,635,636,637,638,639,640,641,642,643,644,645,646,647,648,649,650,651,652,653,654,655,656,657,658,659,660,661,662,663,664,665,666,667,668,669,670,671,672,673,674,675,676,677,678,679,680,681,682,683,684,685,686,687,688,689,690,691,692,693,694,695,696,697,698,699,700,701,702,703,704,705,706,707,708,709,710,711,712,713,714,715,716,717,718,719,720,721,722,723,724,725,726,727,728,729,730,731,732,733,734,735,736,737,738,739,740,741,742,743,744,745,746,747,748,749,750,751,752,753,754,755,756,757,758,759,760,761,762,763,764,765,766,767,768,769,770,771,772,773,774,775,776,777,778,779,780,781,782,783,784,785,786,787,788,789,790,791,792,793,794,795,796,797,798,799,800,801,802,803,804,805,806,807,808,809,810,811,812,813,814,815,816,817,818,819,820,821,822,823,824,825,826,827,828,829,830,831,832,833,834,835,836,837,838,839,840,841,842,843,844,845,846,847,848,849,850,851,852,853,854,855,856,857,858,859,860,861,862,863,864,865,866,867,868,869,870,871,872,873,874,875,876,877,878,879,880,881,882,883,884,885,886,887,888,889,890,891,892,893,894,895,896,897,898,899,900,901,902,903,904,905,906,907,908,909,910,911,912,913,914,915,916,917,918,919,920,921,922,923,924,925,926,927,928,929,930,931,932,933,934,935,936,937,938,939,940,941,942,943,944,945,946,947,948,949,950,951,952,953,954,955,956,957,958,959,960,961,962,963,964,965,966,967,968,969,970,971,972,973,974,975,976,977,978,979,980,981,982,983,984,985,986,987,988,989,990,991,992,993,994,995,996,997,998,999,1000,1001,1002,1003,1004,1005,1006,1007,1008,1009,1010,1011,1012,1013,1014,1015,1016,1017,1018,1019,1020,1021,1022,1023,1024,1025,1026,1027,1028,1029,1030,1031,1032,1033,1034,1035,1036,1037,1038,1039,1040,1041,1042,1043,1044,1045,1046,1047,1048,1049,1050,1051,1052,1053,1054,1055,1056,1057,1058,1059,1060,1061,1062,1063,1064,1065,1066,1067,1068,1069,1070,1071,1072,1073,1074,1075,1076,1077,1078,1079,1080,1081,1082,1083,1084,1085,1086,1087,1088,1089,1090,1091,1092,1093,1094,1095,1096,1097,1098,1099,1100,1101,1102,1103,1104,1105,1106,1107,1108,1109,1110,1111,1112,1113,1114,1115,1116,1117,1118,1119,1120,1121,1122,1123,1124,1125,1126,1127,1128,1129,1130,1131,1132,1133,1134,1135,1136,1137,1138,1139,1140,1141,1142,1143,1144,1145,1146,1147,1148,1149,1150,1151,1152,1153,1154,1155,1156,1157,1158,1159,1160,1161,1162,1163,1164,1165,1166,1167,1168,1169,1170,1171,1172,1173,1174,1175,1176,1177,1178,1179,1180,1181,1182,1183,1184,1185,1186,1187,1188,1189,1190,1191,1192,1193,1194,1195,1196,1197,1198,1199,1200,1201,1202,1203,1204,1205,1206,1207,1208,1209,1210,1211,1212,1213,1214,1215,1216,1217,1218,1219,1220,1221,1222,1223,1224,1225,1226,1227,1228,1229,1230,1231,1232,1233,1234,1235,1236,1237,1238,1239,1240,1241,1242,1243,1244,1245,1246,1247,1248,1249,1250,1251,1252,1253,1254,1255,1256,1257,1258,1259,1260,1261,1262,1263,1264,1265,1266,1267,1268,1269,1270,1271,1272,1273,1274,1275,1276,1277,1278,1279,1280,1281,1282,1283,1284,1285,1286,1287,1288,1289,1290,1291,1292,1293,1294,1295,1296,1297,1298,1299,1300,1301,1302,1303,1304,1305,1306,1307,1308,1309,1310,1311,1312,1313,1314,1315,1316,1317,1318,1319,1320,1321,1322,1323,1324,1325,1326,1327,1328,1329,1330,1331,1332,1333,1334,1335,1336,1337,1338,1339,1340,1341,1342,1343,1344,1345,1346,1347,1348,1349,1350,1351,1352,1353,1354,1355,1356,1357,1358,1359,1360,1361,1362,1363,1364,1365,1366,1367,1368,1369,1370,1371,1372,1373,1374,1375,1376,1377,1378,1379,1380,1381,1382,1383,1384,1385,1386,1387,1388,1389,1390,1391,1392,1393,1394,1395,1396,1397,1398,1399,1400,1401,1402,1403,1404,1405,1406,1407,1408,1409,1410,1411,1412,1413,1414,1415,1416,1417,1418,1419,1420,1421,1422,1423,1424,1425,1426,1427,1428,1429,1430,1431,1432,1433,1434,1435,1436,1437,1438,1439,1440,1441,1442,1443,1444,1445,1446,1447,1448,1449,1450,1451,1452,1453,1454,1455,1456,1457,1458,1459,1460,1461,1462,1463,1464,1465,1466,1467,1468,1469,1470,1471,1472,1473,1474,1475,1476,1477,1478,1479,1480,1481,1482,1483,1484,1485,1486,1487,1488,1489,1490,1491,1492,1493,1494,1495,1496,1497,1498,1499,1500,1501,1502,1503,1504,1505,1506,1507,1508,1509,1510,1511,1512,1513,1514,1515,1516,1517,1518,1519,1520,1521,1522,1523,1524,1525,1526,1527,1528,1529,1530,1531,1532,1533,1534,1535,1536,1537,1538,1539,1540,1541,1542,1543,1544,1545,1546,1547,1548,1549,1550,1551,1552,1553,1554,1555,1556,1557,1558,1559,1560,1561,1562,1563,1564,1565,1566,1567,1568,1569,1570,1571,1572,1573,1574,1575,1576,1577,1578,1579,1580,1581,1582,1583,1584,1585,1586,1587,1588,1589,1590,1591,1592,1593,1594,1595,1596,1597,1598,1599,1600,1601,1602,1603,1604,1605,1606,1607,1608,1609,1610,1611,1612,1613,1614,1615,1616,1617,1618,1619,1620,1621,1622,1623,1624,1625,1626,1627,1628,1629,1630,1631,1632,1633,1634,1635,1636,1637,1638,1639,1640,1641,1642,1643,1644,1645,1646,1647,1648,1649,1650,1651,1652,1653,1654,1655,1656,1657,1658,1659,1660,1661,1662,1663,1664,1665,1666,1667,1668,1669,1670,1671,1672,1673,1674,1675,1676,1677,1678,1679,1680,1681,1682,1683,1684,1685,1686,1687,1688,1689,1690,1691,1692,1693,1694,1695,1696,1697,1698,1699,1700,1701,1702,1703,1704,1705,1706,1707,1708,1709,1710,1711,1712,1713,1714,1715,1716,1717,1718,1719,1720,1721,1722,1723,1724,1725,1726,1727,1728,1729,1730,1731,1732,1733,1734,1735,1736,1737,1738,1739,1740,1741,1742,1743,1744,1745,1746,1747,1748,1749,1750,1751,1752,1753,1754,1755,1756,1757,1758,1759,1760,1761,1762,1763,1764,1765,1766,1767,1768,1769,1770,1771,1772,1773,1774,1775,1776,1777,1778,1779,1780,1781,1782,1783,1784,1785,1786,1787,1788,1789,1790,1791,1792,1793,1794,1795,1796,1797,1798,1799,1800,1801,1802,1803,1804,1805,1806,1807,1808,1809,1810,1811,1812,1813,1814,1815,1816,1817,1818,1819,1820,1821,1822,1823,1824,1825,1826,1827,1828,1829,1830,1831,1832,1833,1834,1835,1836,1837,1838,1839,1840,1841,1842,1843,1844,1845,1846,1847,1848,1849,1850,1851,1852,1853,1854,1855,1856,1857,1858,1859,1860,1861,1862,1863,1864,1865,1866,1867,1868,1869,1870,1871,1872,1873,1874,1875,1876,1877,1878,1879,1880,1881,1882,1883,1884,1885,1886,1887,1888,1889,1890,1891,1892,1893,1894,1895,1896,1897,1898,1899,1900,1901,1902,1903,1904,1905,1906,1907,1908,1909,1910,1911,1912,1913,1914,1915,1916,1917,1918,1919,1920,1921,1922,1923,1924,1925,1926,1927,1928,1929,1930,1931,1932,1933,1934,1935,1936,1937,1938,1939,1940,1941,1942,1943,1944,1945,1946,1947,1948,1949,1950,1951,1952,1953,1954,1955,1956,1957,1958,1959,1960,1961,1962,1963,1964,1965,1966,1967,1968,1969,1970,1971,1972,1973,1974,1975,1976,1977,1978,1979,1980,1981,1982,1983,1984,1985,1986,1987,1988,1989,1990,1991,1992,1993,1994,1995,1996,1997,1998,1999,2000,2001,2002,2003,2004,2005,2006,2007,2008,2009,2010,2011,2012,2013,2014,2015,2016,2017,2018,2019,2020,2021,2022,2023,2024,2025,2026,2027,2028,2029,2030,2031,2032,2033,2034,2035,2036,2037,2038,2039,2040,2041,2042,2043,2044,2045,2046,2047,2048,2049,2050,2051,2052,2053,2054,2055,2056,2057,2058,2059,2060,2061,2062,2063,2064,2065,2066,2067,2068,2069,2070,2071,2072,2073,2074,2075,2076,2077,2078,2079,2080,2081,2082,2083,2084,2085,2086,2087,2088,2089,2090,2091,2092,2093,2094,2095,2096,2097,2098,2099,2100,2101,2102,2103,2104,2105,2106,2107,2108,2109,2110,2111,2112,2113,2114,2115,2116,2117,2118,2119,2120,2121,2122,2123,2124,2125,2126,2127,2128,2129,2130,2131,2132,2133,2134,2135,2136,2137,2138,2139,2140,2141,2142,2143,2144,2145,2146,2147,2148,2149,2150,2151,2152,2153,2154,2155,2156,2157,2158,2159,2160,2161,2162,2163,2164,2165,2166,2167,2168,2169,2170,2171,2172,2173,2174,2175,2176,2177,2178,2179,2180,2181,2182,2183,2184,2185,2186,2187,2188,2189,2190,2191,2192,2193,2194,2195,2196,2197,2198,2199,2200,2201,2202,2203,2204,2205,2206,2207,2208,2209,2210,2211,2212,2213,2214,2215,2216,2217,2218,2219,2220,2221,2222,2223,2224,2225,2226,2227,2228,2229,2230,2231,2232,2233,2234,2235,2236,2237,2238,2239,2240,2241,2242,2243,2244,2245,2246,2247,2248,2249,2250,2251,2252,2253,2254,2255,2256,2257,2258,2259,2260,2261,2262,2263,2264,2265,2266,2267,2268,2269,2270,2271,2272,2273,2274,2275,2276,2277,2278,2279,2280,2281,2282,2283,2284,2285,2286,2287,2288,2289,2290,2291,2292,2293,2294,2295,2296,2297,2298,2299,2300,2301,2302,2303,2304,2305,2306,2307,2308,2309,2310,2311,2312,2313,2314,2315,2316,2317,2318,2319,2320,2321,2322,2323,2324,2325,2326,2327,2328,2329,2330,2331,2332,2333,2334,2335,2336,2337,2338,2339,2340,2341,2342,2343,2344,2345,2346,2347,2348,2349,2350,2351,2352,2353,2354,2355,2356,2357,2358,2359,2360,2361,2362,2363,2364,2365,2366,2367,2368,2369,2370,2371,2372,2373,2374,2375,2376,2377,2378,2379,2380,2381,2382,2383,2384,2385,2386,2387,2388,2389,2390,2391,2392,2393,2394,2395,2396,2397,2398,2399,2400,2401,2402,2403,2404,2405,2406,2407,2408,2409,2410,2411,2412,2413,2414,2415,2416,2417,2418,2419,2420,2421,2422,2423,2424,2425,2426,2427,2428,2429,2430,2431,2432,2433,2434,2435,2436,2437,2438,2439,2440,2441,2442,2443,2444,2445,2446,2447,2448,2449,2450,2451,2452,2453,2454,2455,2456,2457,2458,2459,2460,2461,2462,2463,2464,2465,2466,2467,2468,2469,2470,2471,2472,2473,2474,2475,2476,2477,2478,2479,2480,2481,2482,2483,2484,2485,2486,2487,2488,2489,2490,2491,2492,2493,2494,2495,2496,2497,2498,2499,2500,2501,2502,2503,2504,2505,2506,2507,2508,2509,2510,2511,2512,2513,2514,2515,2516,2517,2518,2519,2520,2521,2522,2523,2524,2525,2526,2527,2528,2529,2530,2531,2532,2533,2534,2535,2536,2537,2538,2539,2540,2541,2542,2543,2544,2545,2546,2547,2548,2549,2550,2551,2552,2553,2554,2555,2556,2557,2558,2559,2560,2561,2562,2563,2564,2565,2566,2567,2568,2569,2570,2571,2572,2573,2574,2575,2576,2577,2578,2579,2580,2581,2582,2583,2584,2585,2586,2587,2588,2589,2590,2591,2592,2593,2594,2595,2596,2597,2598,2599,2600,2601,2602,2603,2604,2605,26



**Figure 2-10.**



FULL ADDER NO.	ADDER TYPE	FULL
FA 1-10	I S	
FA 11-16, 21, 22	II M	
FA 17-20	II S	
FA 23, 26	III M	
FA 24, 28	III S	
FA 27, 30	IV M	
FA 29, 31	IV S	
DELAY LATCH NO.	LATCH TYPE	DELAY
DL 3, 5, 11, 23, 31	I M	
DL 12, 13, 26	II S	
DL 17, 22, 29, 30	II S	
DL 20, 24, 31, 32, 34	II M	
DL 35, 36	II S	
DL 21, 27	III M	
DL 33	III S	
DL 37	IV M	
DL 37	IV S	

APPROVALS DATE

DIGITAL SUMMATION  
32 DOC

REV. A. 4-18-70 C.V.

OUTPUT SIGNAL COUNT

1-14 16  
15-16 10  
17-18 5  
19-20 5  
TOTAL DIGIT SUMMER PINS 31

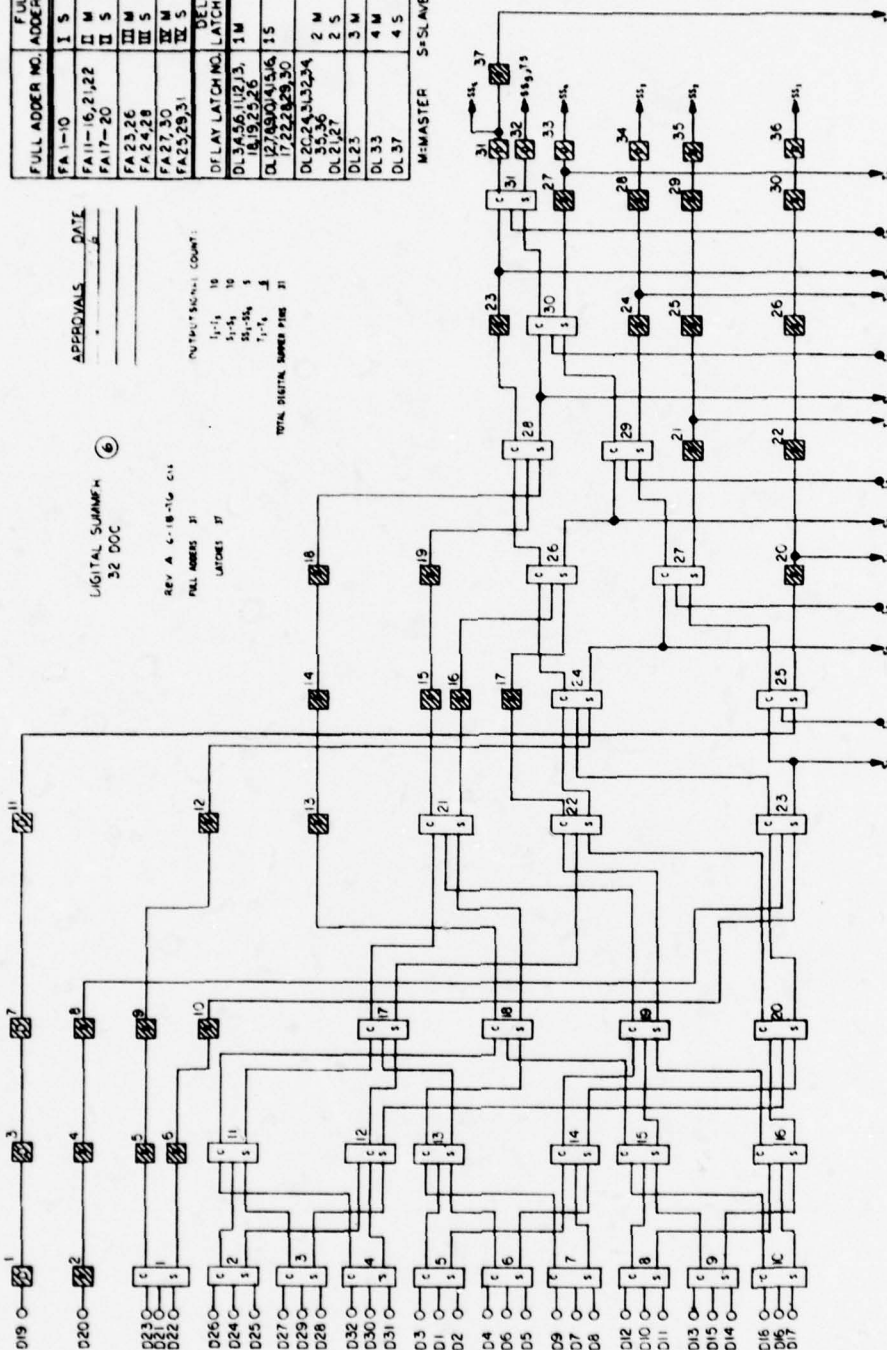
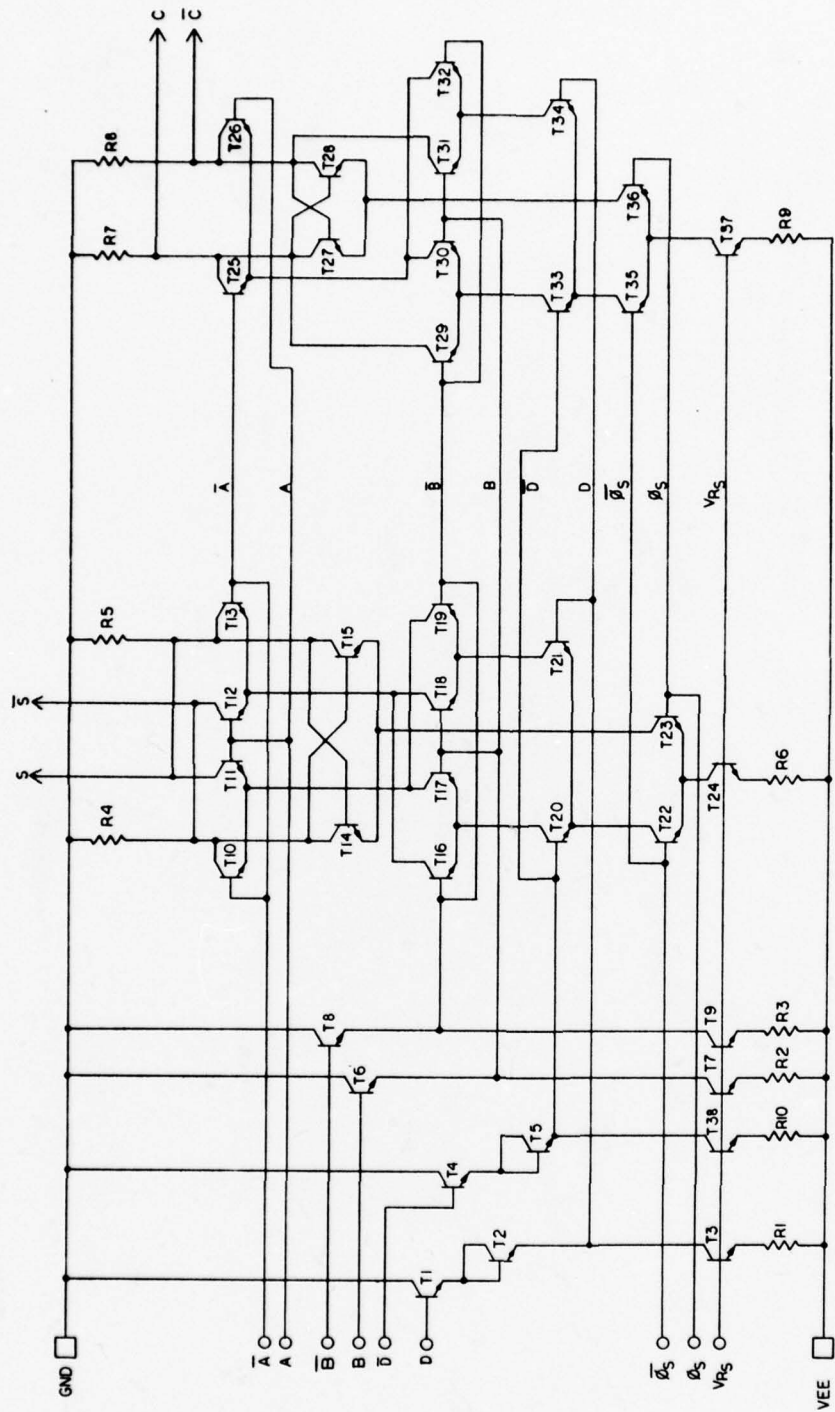


Figure 2-11.



DIFF. RESISTOR VALUES IN OHMS AT 2400PS

32 DOC (MASTER)

[PART OF MC93]

REV 6, 6-10-76

R1, R2, R3, R10 = 48K  
R4, 5, 7, 8 = 1K  
R6, 9 = 2120

DEVELOPMENT  
APPROVALS  
DATE: 1/10/76  
BY: J. B. B. JR.  
REV 6, 6-10-76

NOTE: WHEN USED AS SLAVE  
REVERSE 0 & 0

Figure 2-12.

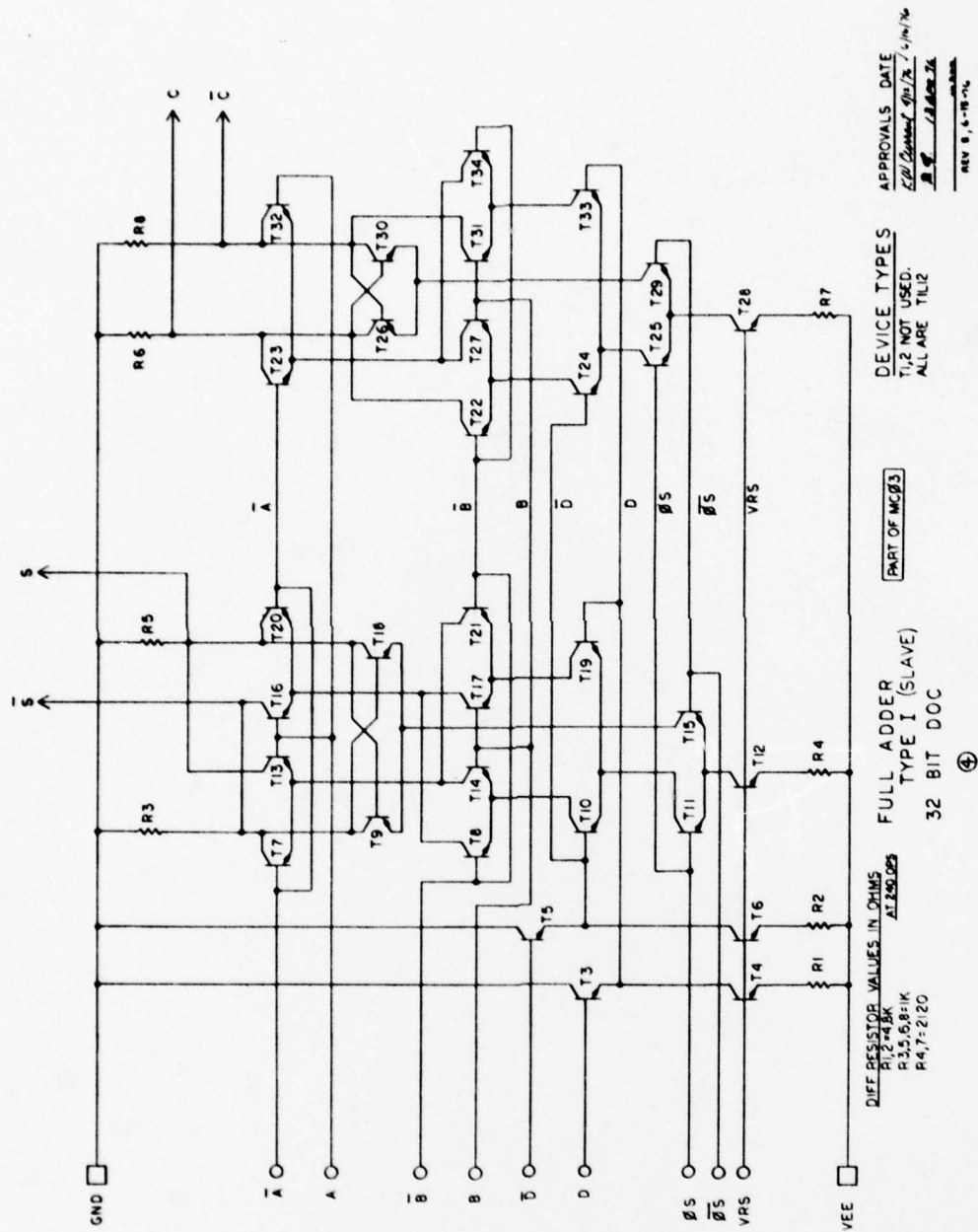


Figure 2-13.

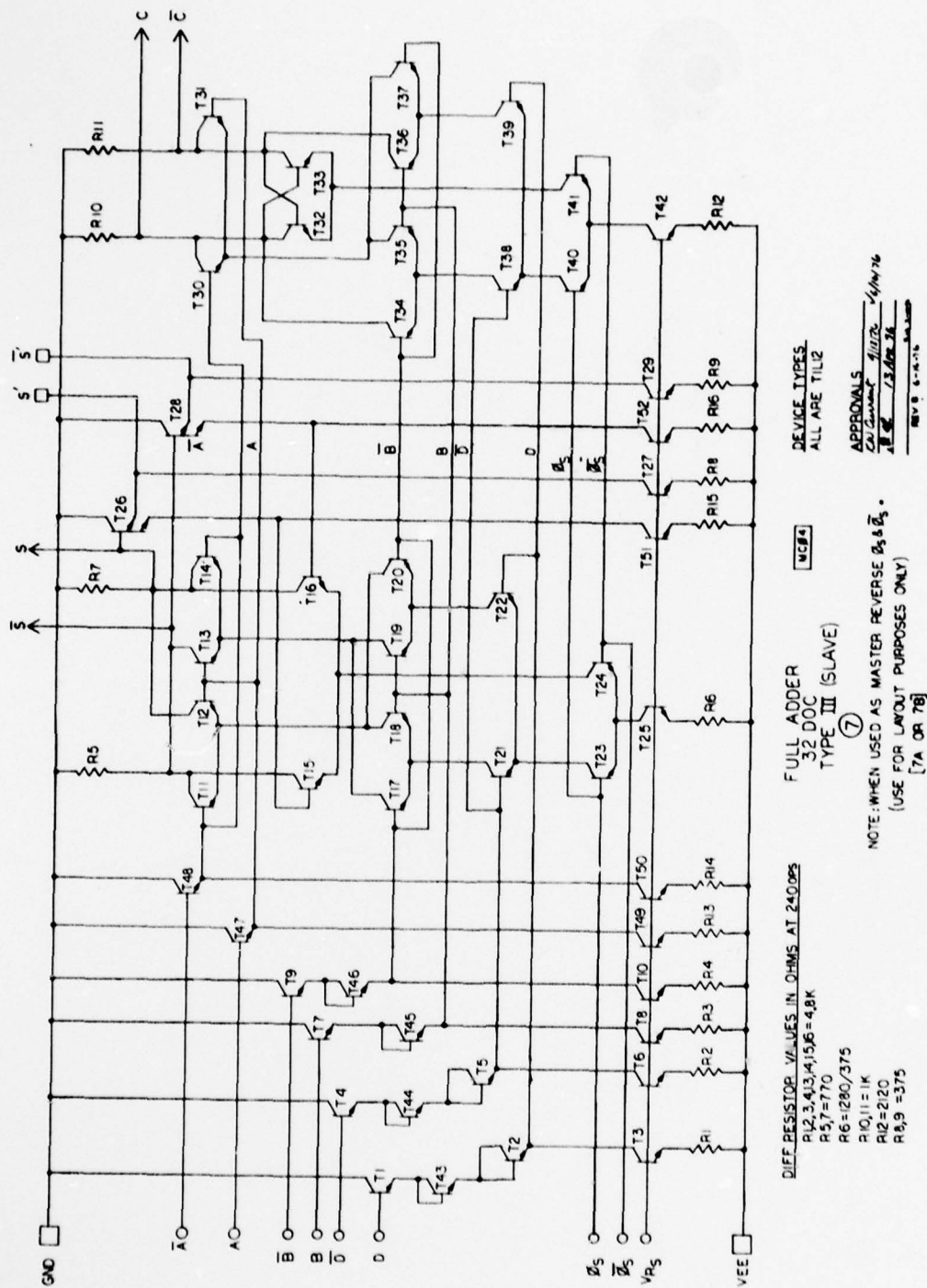
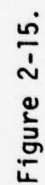


Figure 2-14.





The reference voltages which control the current sources in the digital circuitry are shown in Figures 2-11 and 2-22. One controls the shift registers and exclusive-OR gates of the correlator section, and the other controls the summer. The reference generator for the summer normally has the input labelled " $S_C$ " tied to ground. The summer can be turned off by disconnecting this pad if only the analog correlator function is required. The two circuits are essentially identical in operation. They consist of a bandgap regulator cell to generate temperature-independent voltage which is then used to generate a voltage to drive the current sources to provide constant current. There is also circuitry to compensate the output against power supply variations.

The analog reference circuit in Figure 2-23 drives the current sources that are summed into the analog correlator output. An external resistor is used to set the full scale current output. This circuit also corrects for variations in transistor gain that would otherwise cause the output current to vary.

The clock buffers in Figures 2-24 and 2-25 provide correct levels to operate the shift registers and summer. When the summer is configured to provide ECL output levels, an optional additional level shift is included in the summer clock buffer to avoid saturating the clock transistors in the summer.

A photograph of the packaged 32-DOC-1 circuit is shown in Figure 2-25. The chip shown is configured for ECL outputs from the summer. It is packaged in a standard 5/8" diameter round flatpack with 40 leads. Leads are on .050" centers.

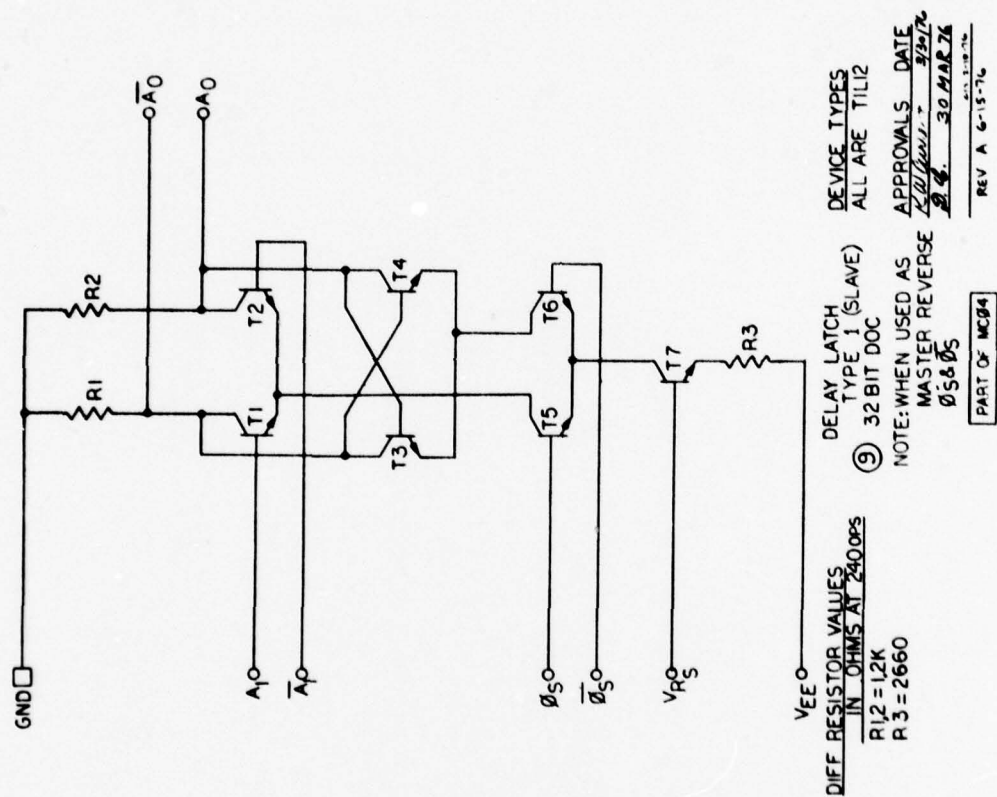


Figure 2-16.

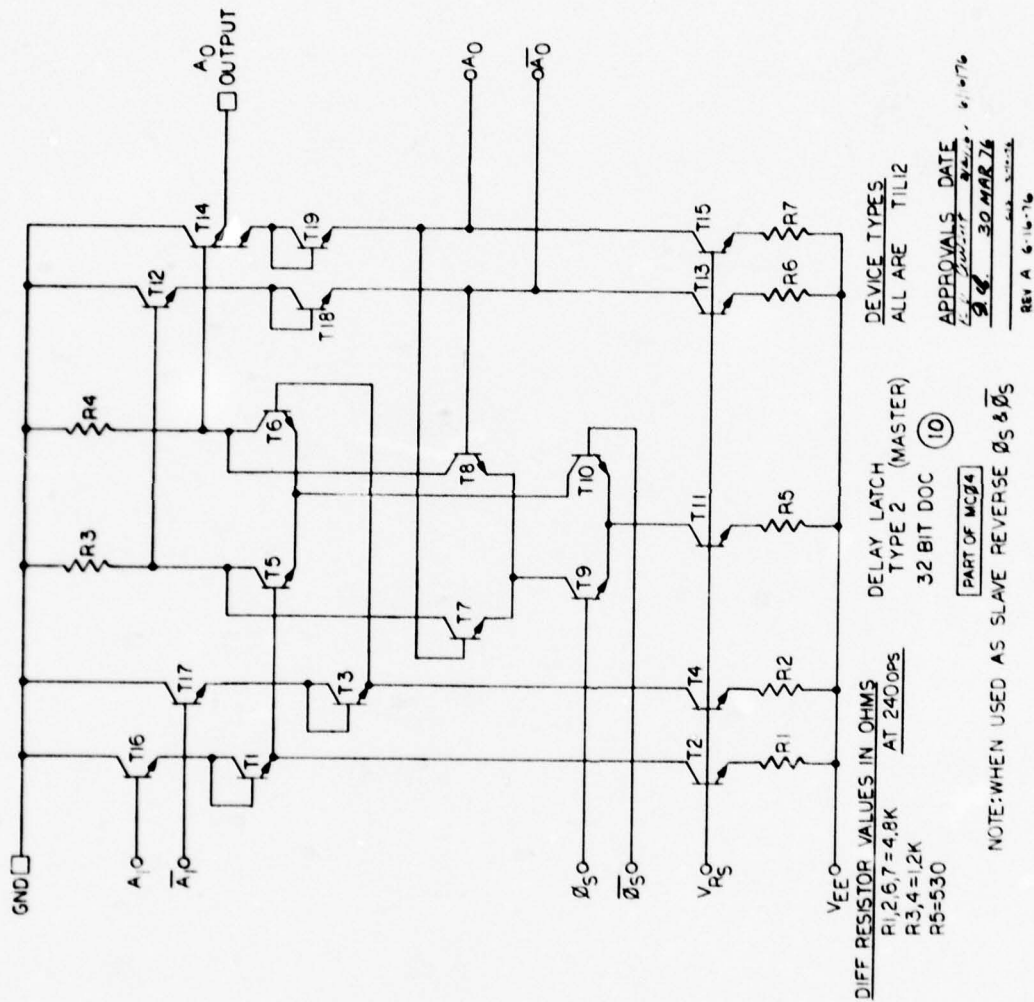


Figure 2-17.



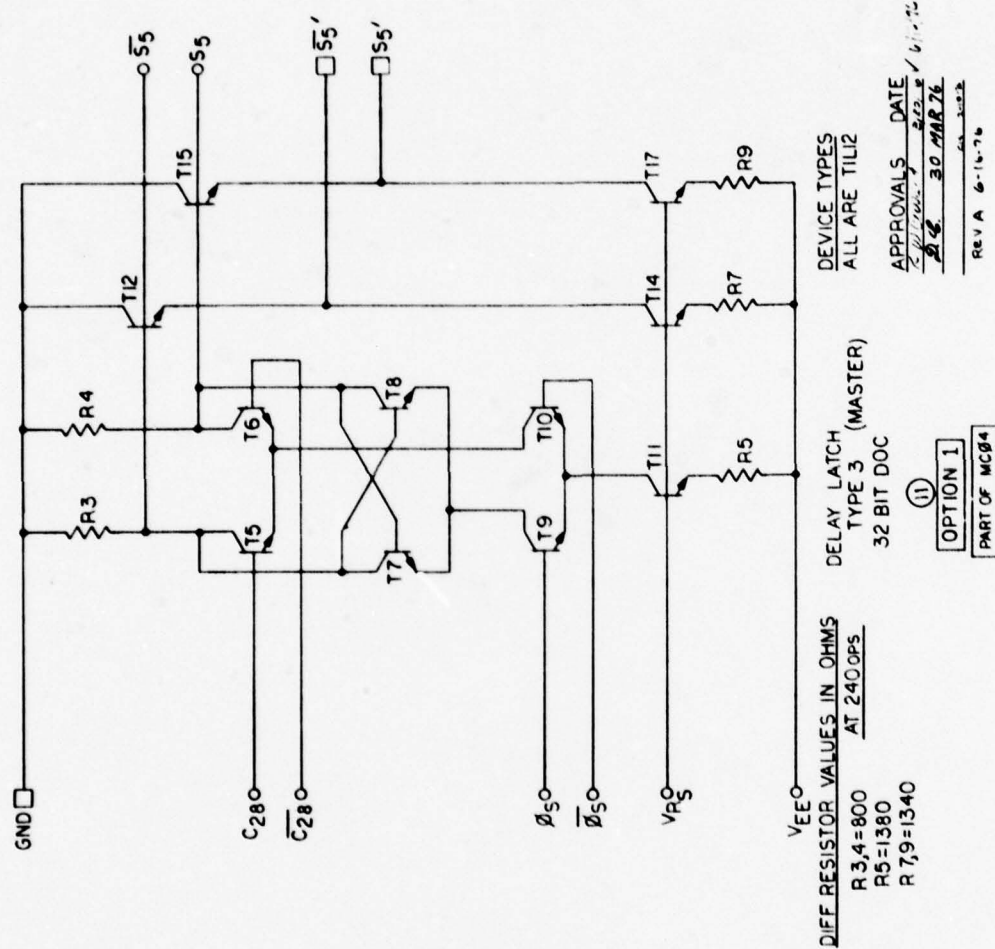


Figure 2-18.

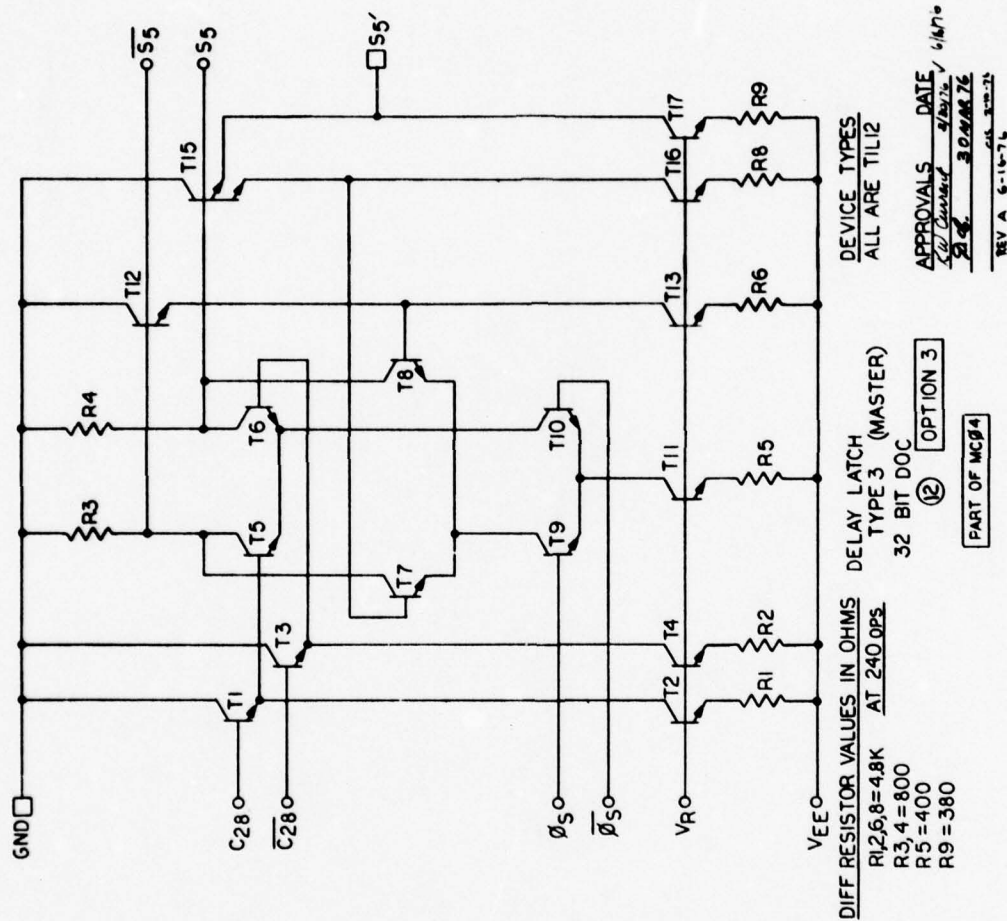


Figure 2-19.

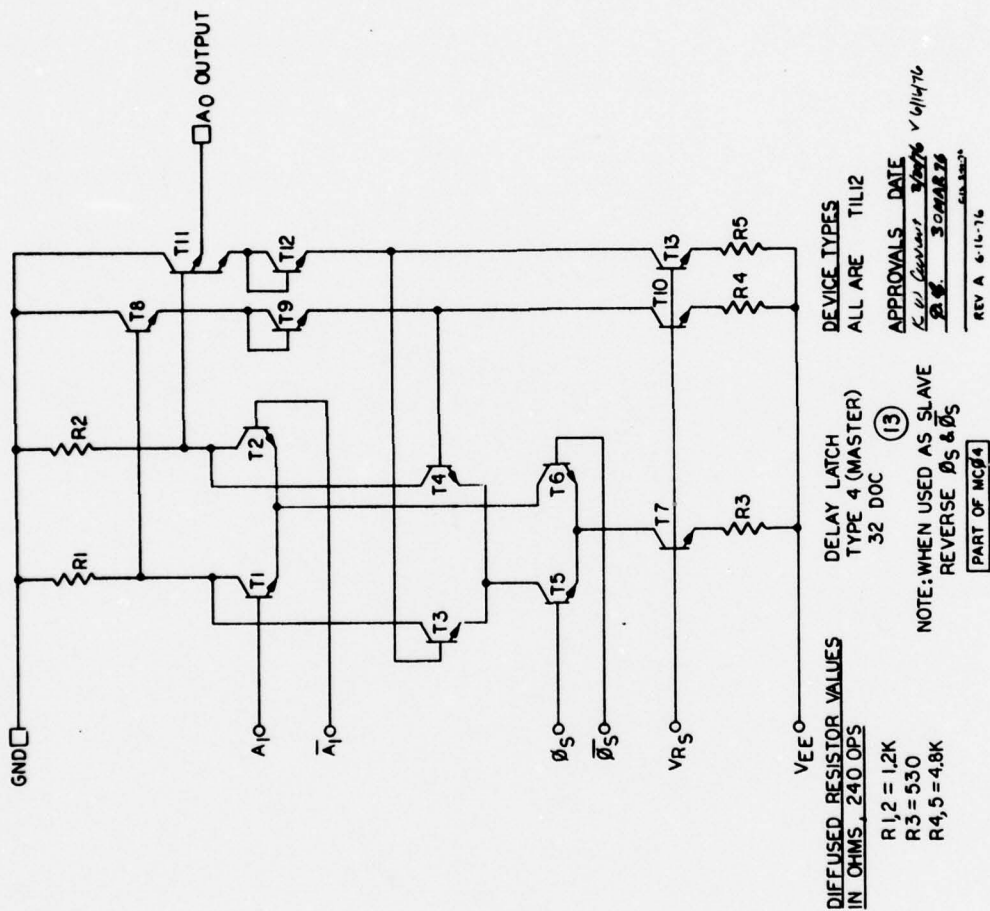
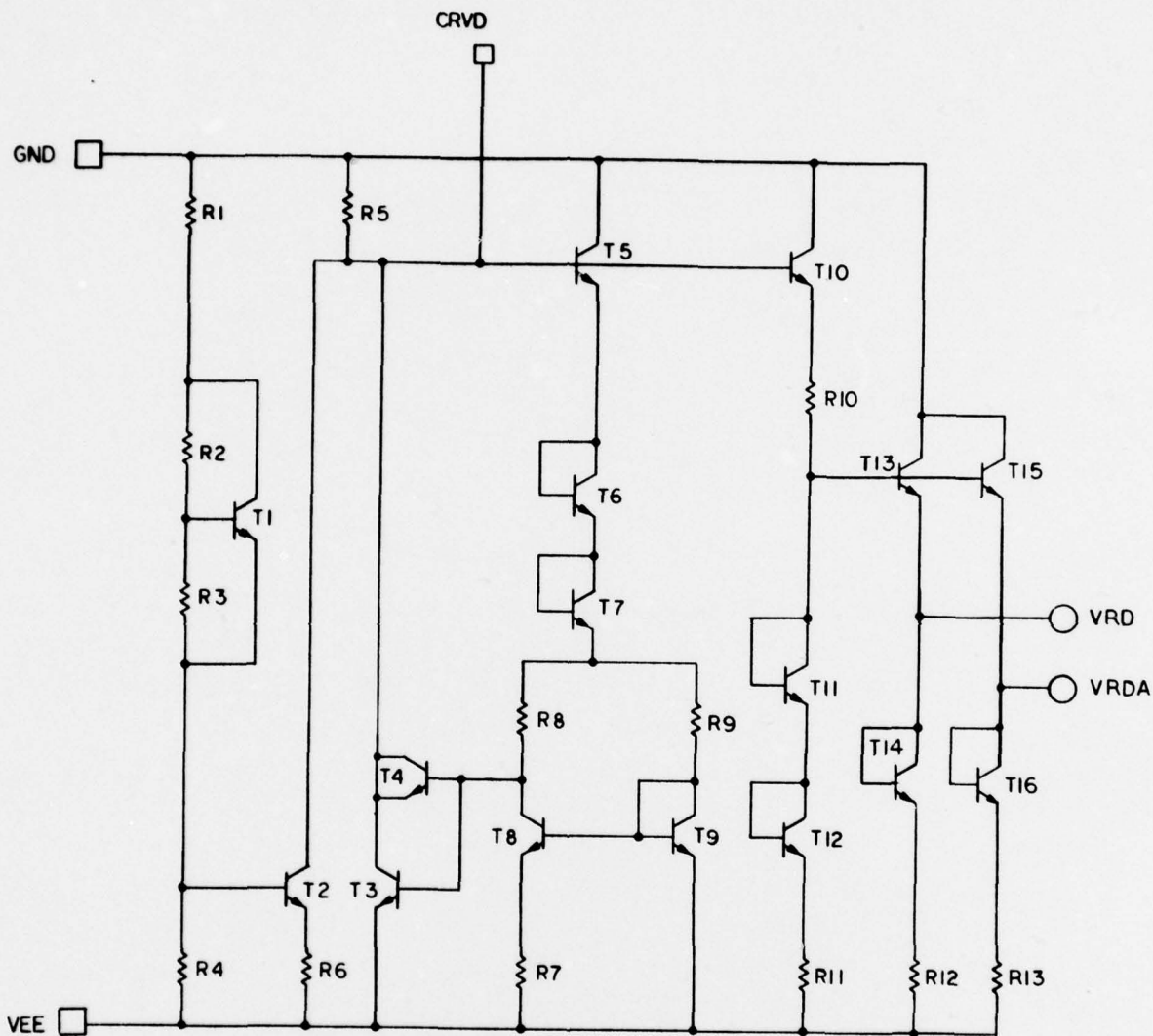


Figure 2-20.



# DIFF RESISTOR VALUES AT 240ops

R1=22.8K  
 R2=21.2K  
 R3=21K  
 R4=11.4K  
 R5=2.6K  
 R6=850  
 R7=253  
 R8,9=29K  
 R10= 750  
 R11 = 400  
 R12 = 900  
 R13 = 400

32 DOC  
 VRD

14

PART OF MC05

# DEVICE TYPES

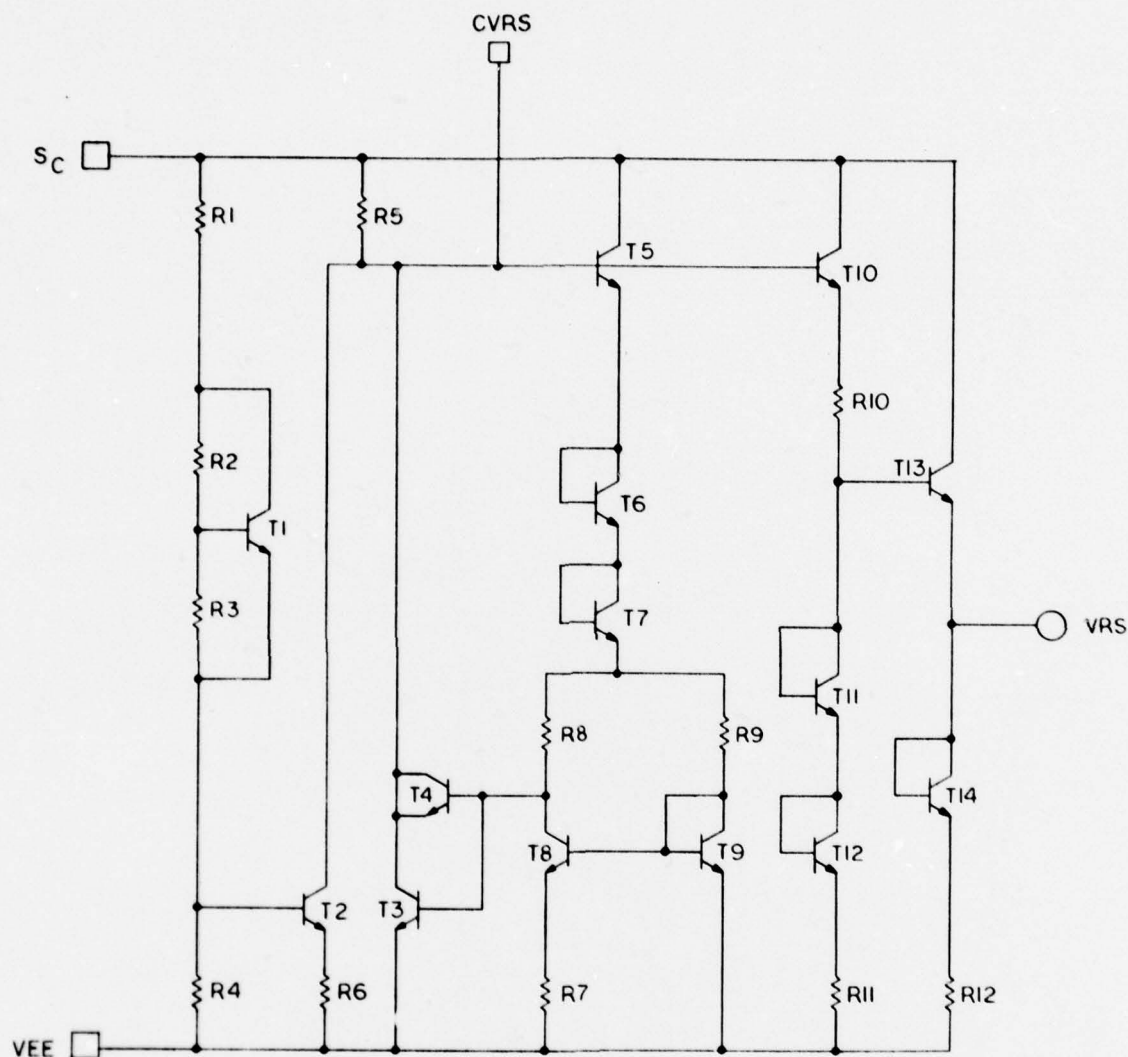
ALL ARE TIL12 EXCEPT T4,T8  
 T8=T5L12  
 T4=T2L117

APPROVALS DATE  
 10/2/76 / 10/2/76  
 205 13 APR 76

REV D 8-10-77

Figure 2-21.





DIFF RESISTOR VALUES AT 240 ops

R1=22.8K	R10=345
R2=21.2K	R11=200
R3=21K	R12=320
R4=11.4K	
R5=2.6K	
R6=850	
R7=253	
R8,9=2.9K	

32 DOC  
VRS

(14A)

PART OF MC05

DEVICE TYPES

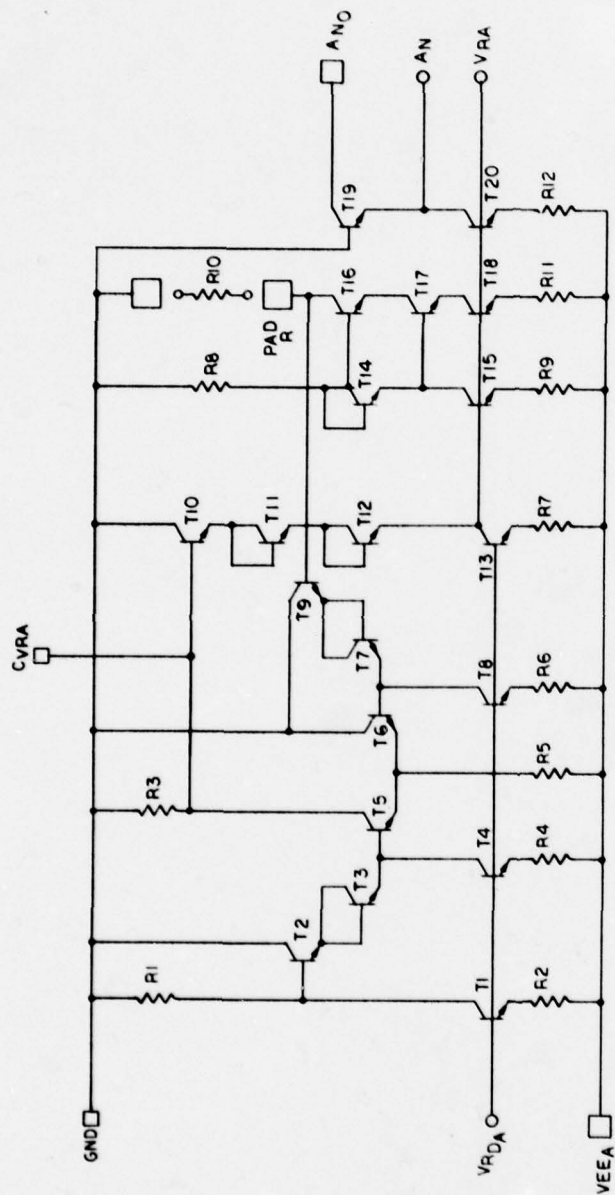
ALL ARE TIL12 EXCEPT T4,T8  
T8=T5L12  
T4=T2L117

APPROVALS DATE

*[Signature]* 4/13/76 V. G. 13 APR 76

REV D 5-20-77

Figure 2-22.



VRA 32 BIT DOC (17)

DIFF. RESISTOR VALUES AT 240ops

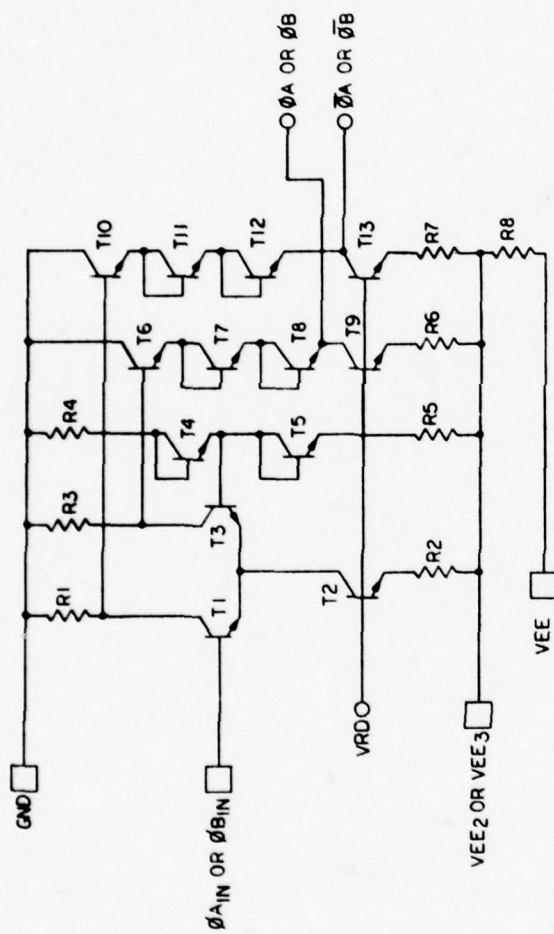
R1= (OPTION 1) 6.9K \* R10= (OPTION 1) 6.9K  
 R1= (OPTION 3) 10.9K \* R10= (OPTION 3) 10.9K  
 R2, 4, 6, 7 = 2180  
 R3= (OPTION 1) 4770  
 R3= (OPTION 3) 7200

\* NOTE:  
 R5= 2570  
 R8= (OPTION 1) 7.5K  
 R8= (OPTION 3) 11.54K  
 R9= 3940

DEVICES TYPE  
 ALL ARE T1L12  
 EXCEPT FOR T19 = T2L12

APPROVALS DATE  
 K.W. Current 9/12/76  
 13 APR 76  
 6-14-76

Figure 2-23.



32 DOC

CLOCK A AND B

(5) PART OF MC05

DIFF. RESISTOR VALUES IN OHMS AT 240 OPS.

R1, R3 = 150  
R2 = 187  
R4 = 2.76K  
R5 = 18.8K (OPTION 1)  
R5 = 23.6K (OPTION 3)  
R6, R7 = 85  
R8 = 13

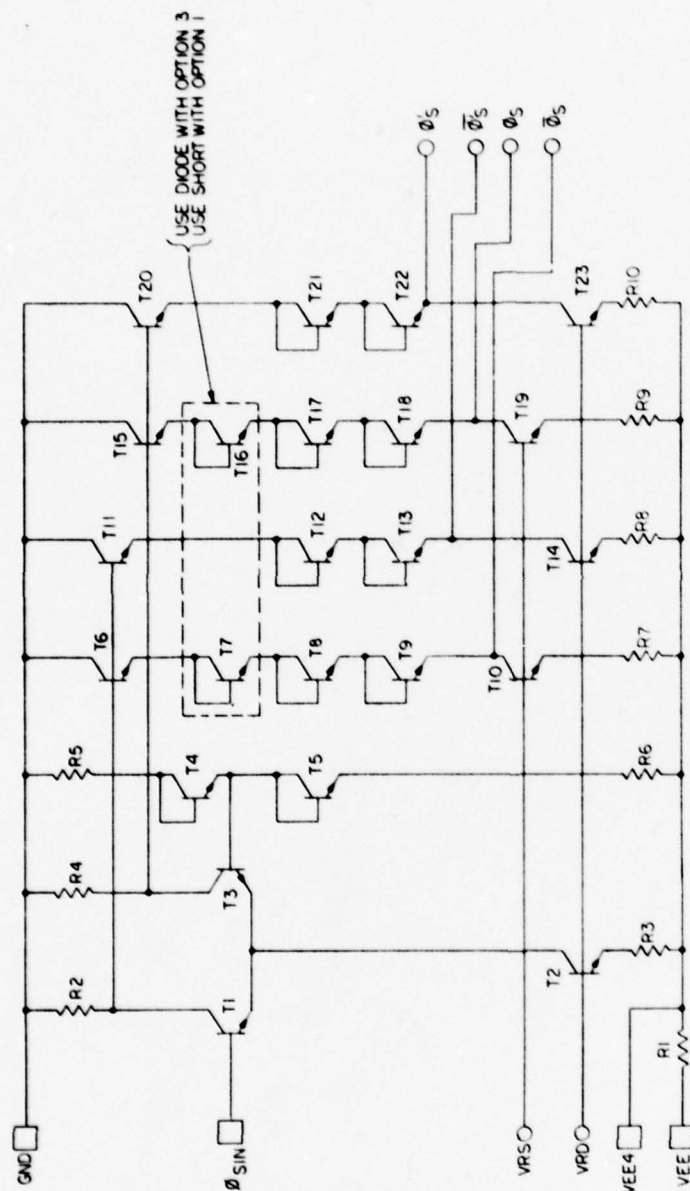
(EXTERNAL PULLDOWN RESISTANCE OF 1080Ω MUST BE PROVIDED AT Ø INPUT TERMINAL.)

DEVICE TYPE  
T6, T8, T9, T11, T12, T13 = T2L12  
ALL OTHERS T1L12

APPROVALS DATE  
P.W. Gammal 4/10/76  
D. G. 13 APR 76

REV B 5-10-76

Figure 2-24.



DIFF RESISTOR VALUES IN OHMS AT 240 OPS

R1 = 3.3  
R2, R4 = 39  
R3 = 43.6  
R5 = 2.76K  
R6 = 18.8K (OPTION 1)  
R6 = 23.6K (OPTION 3)  
R7, R9 = 31  
R8, R10 = 85

DEVICES TYPE  
ALL ARE T2L12 EXCEPT  
T4, T5 = T1L12  
T6, T7, T8, T9, T10, T15, T16, T17, T18, T19 = T3L12

APPROVALS DATE  
11/13/70 13 DEC 70

REV B 5-10-70

(EXTERNAL PULLDOWN RESISTANCE OF 1080Ω  
MUST BE PROVIDED AT 0 TERMINAL)

Figure 2-25.



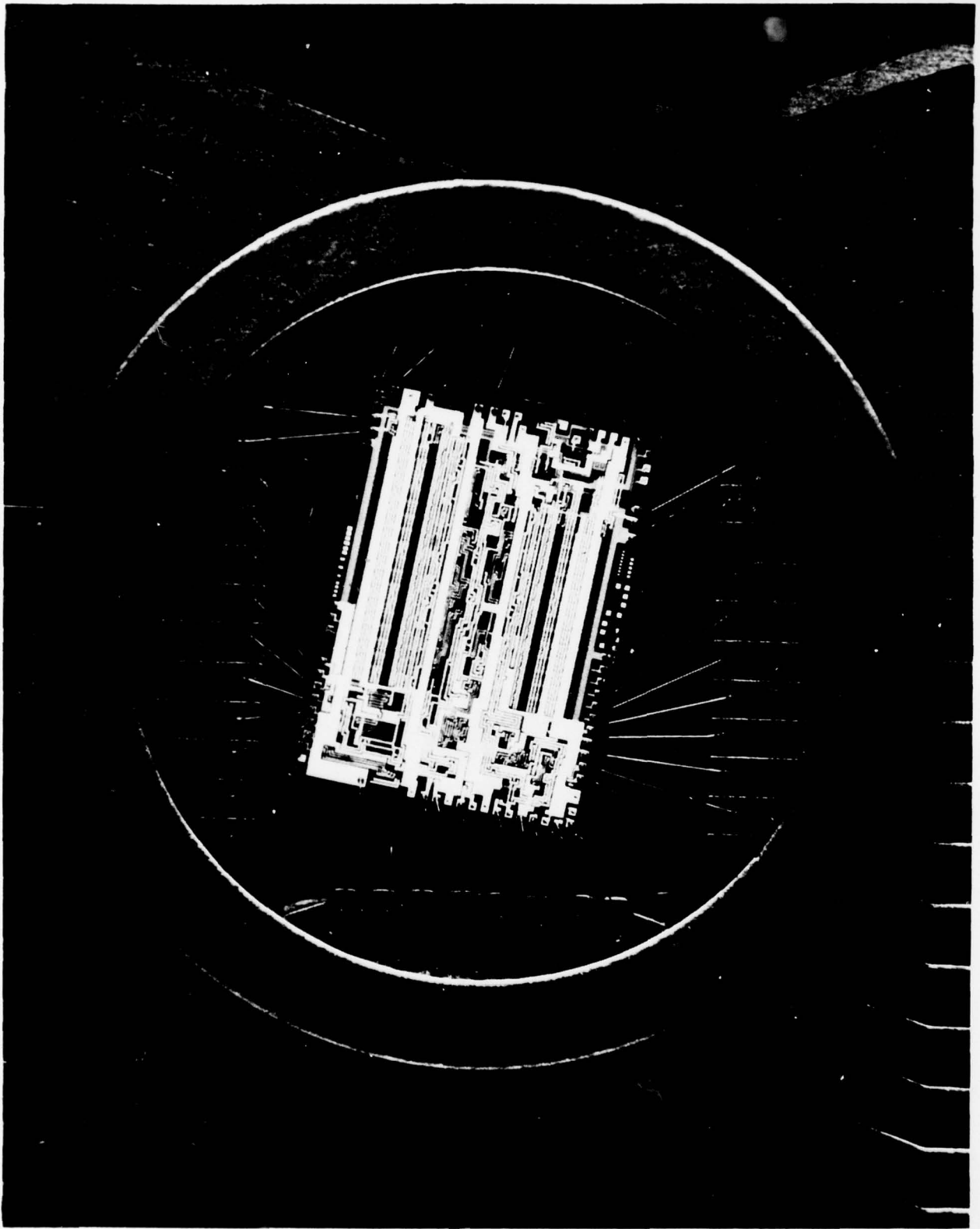


Figure 2-26. 32-D0C-1

### 3. TEST PROCEDURES AND RESULTS

The functional block diagram of the 32-bit digital output correlator is shown in Figure 3-1. Two independently clocked 32-bit shift registers are compared bit by bit by 32 exclusive-OR circuits. Each exclusive-OR circuit controls a D/A current source, the output currents of which are summed into a common node to produce an analog output correlation function. The exclusive-OR circuit also provides a digital signal to the 32-bit digital summer which produces a binary-coded digital word representing the sum of digits which agree at any one time between the two shift registers.

A simple test was designed to test for functionality of the device, both at wafer probe and in packaged form. A 32-bit word is shifted through one shift register, while the other is held static. The analog output of a properly functioning circuit is a 32-bit staircase function. The test set is arranged so that the conditions can be reversed to facilitate looking at both shift register outputs.

A simple circuit for generating the test word is shown in Figure 3-2. This circuit produces inputs for shift registers  $Q_A$  and  $Q_B$ , as well as a scope sync. pulse and clock.

Figure 3-3 shows the analog output of a functional 32-DOC-1 chip. The upper trace shows the output of shift register A, with shift register B held static. The output from the circuit with the input conditions reversed is shown in Figure 3-4.

A convenient way to probe test for 32-DOC-1 circuits with properly functioning digital outputs is to sum the digital outputs into a D/A converter, and then look at the reconstructed output. Figure 3-5 shows a block diagram to take the digital outputs from the device under test, sum them into a D/A converter, and make the output from the D/A available for monitoring on a scope. The output from a functional device should be a 32-bit staircase function.

In order to fully evaluate a working device, the bench tester was designed so that the digital output can be monitored individually.

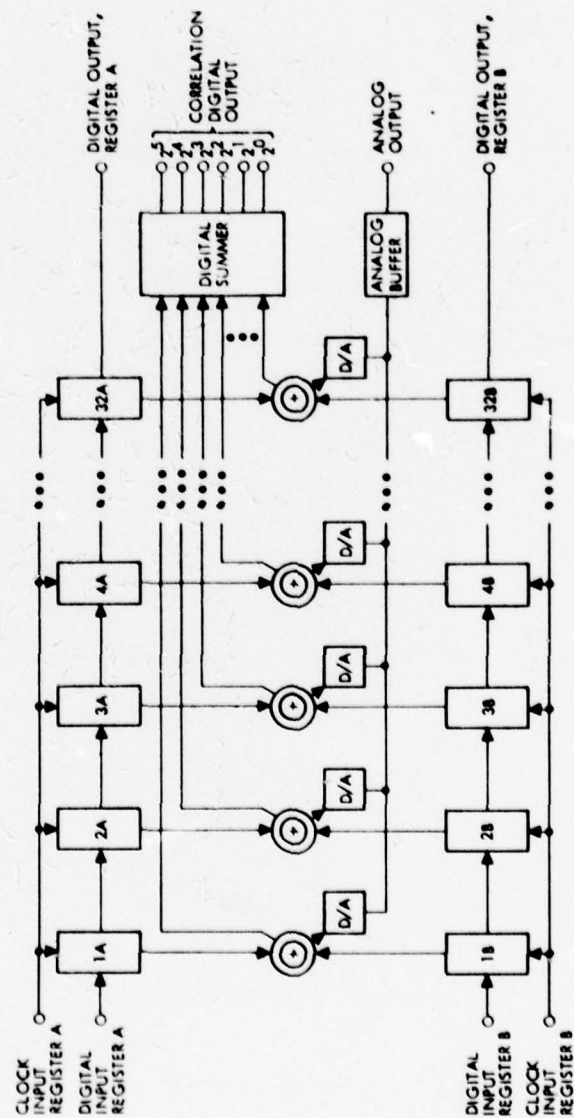
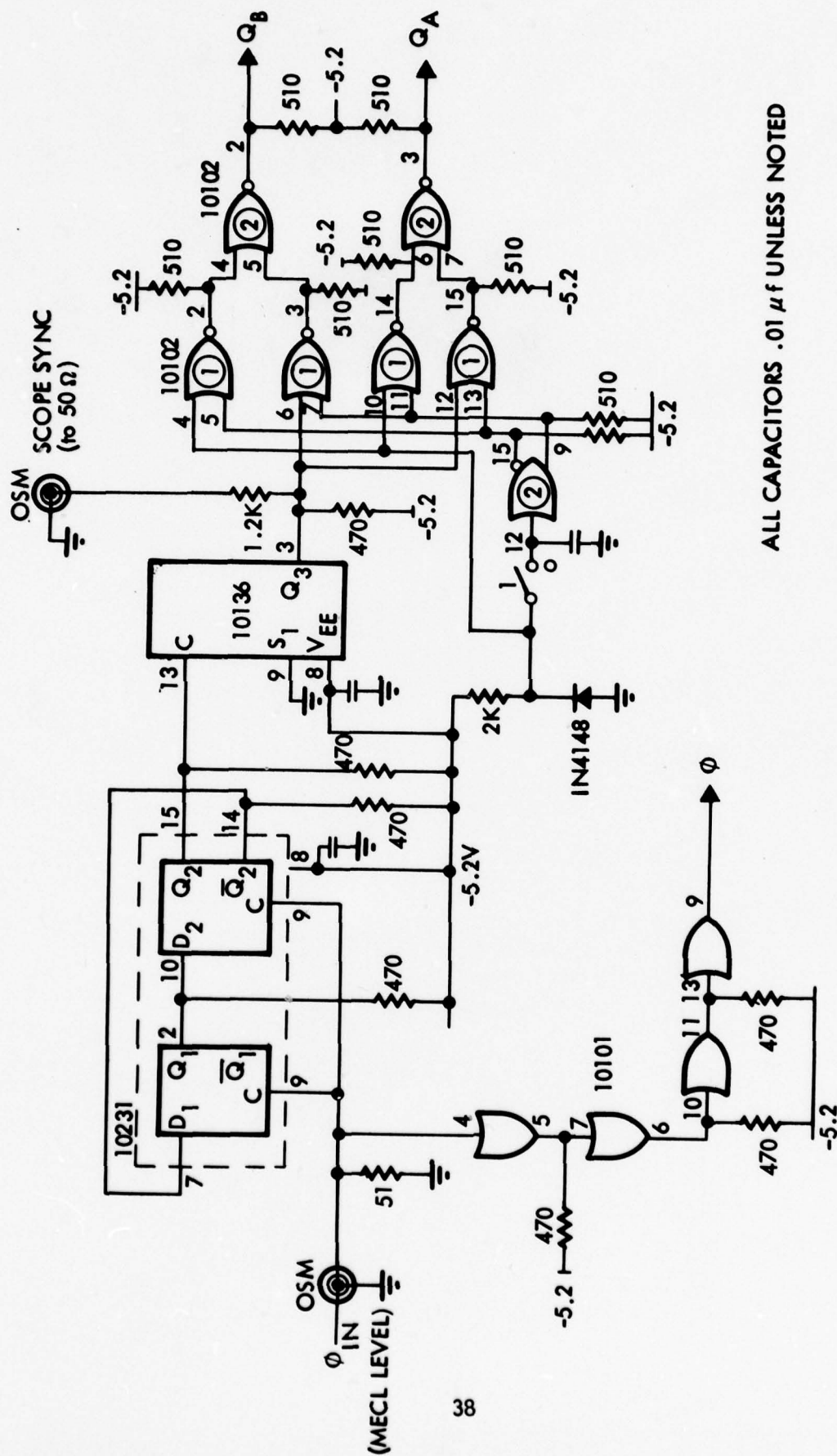


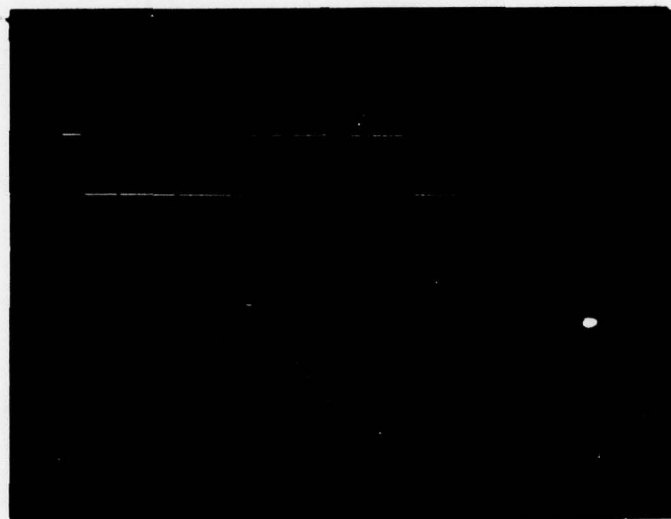
Figure 3-1.



ALL CAPACITORS .01  $\mu$ f UNLESS NOTED

Figure 3-2. 32-D0C-1 Probe Test





SR Output

Analog Output

Figure 3-3. 32-D0C-1 Analog Output



SR Output

Analog Output

Figure 3-4. 32-D0C Analog Output

The test is essentially the same as that used for probe testing. Provision is made for shifting a test word into either shift register,  $Q_A$  or  $Q_B$ , while holding the other static. Each digital output  $SS_1$  to  $SS_6$  may then be looked at individually. A timing diagram showing the relationship of the analog output to the digital outputs is shown in Figure 3-6.

Figure 3-7 shows an expanded analog output showing the relative analog accuracy and linearity of the device, with errors less than  $\pm 5.0\%$ .

The circuits, as tested, have an error in the analog output. An error in the isolation mask sets the current in bit 32 to be the same as bit 31. This results in an analog output with 31 apparent steps. This error requires one mask change to correct it. The digital output functions correctly. Digital outputs,  $2^2$  through  $2^5$ , referenced to the analog output, are shown in Figure 3-8. These may be compared with the timing diagram shown in Figure 3-8. The digital outputs,  $2^0$ ,  $2^1$ ,  $2^2$ ,  $2^3$ ,  $2^4$ , and  $2^5$  are shown in Figure 3-9.

The correlator circuits have been tested at high speed. For the high-speed test, a single bit was shifted into the input  $Q_A$ , and the clock rate increased until the unit failed to operate correctly. Figure 3-9 shows a typical unit operating at 125 MHz. Both shift registers operate at the rated speed. The chip power level is 840 mw. A summary of the test results from the chips tested is shown below in Table 3-1.

Table 3-1. Power Supply,  $V_{EE}$ : -6.0 Volts

Unit	Power mw	Clock Rate MHz
10-115-3-6	804	125
10-115-7-7	894	125
13-146-6-6	864	125
13-146-8-6	876	125
13-146-10-4	870	125
13-146-10-5	828	125

The bonding diagram showing the pin connections is shown in Figure 3-10.

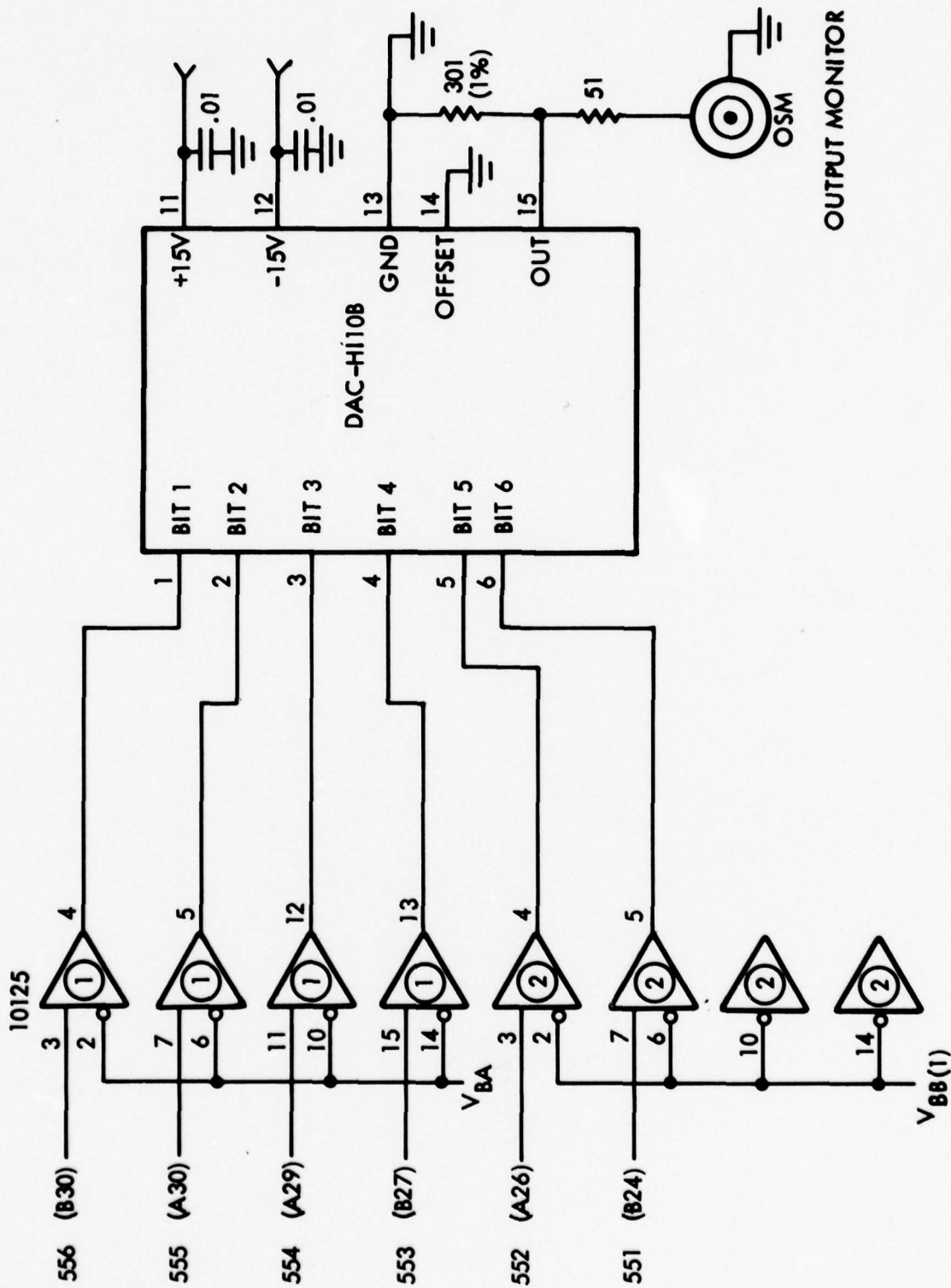
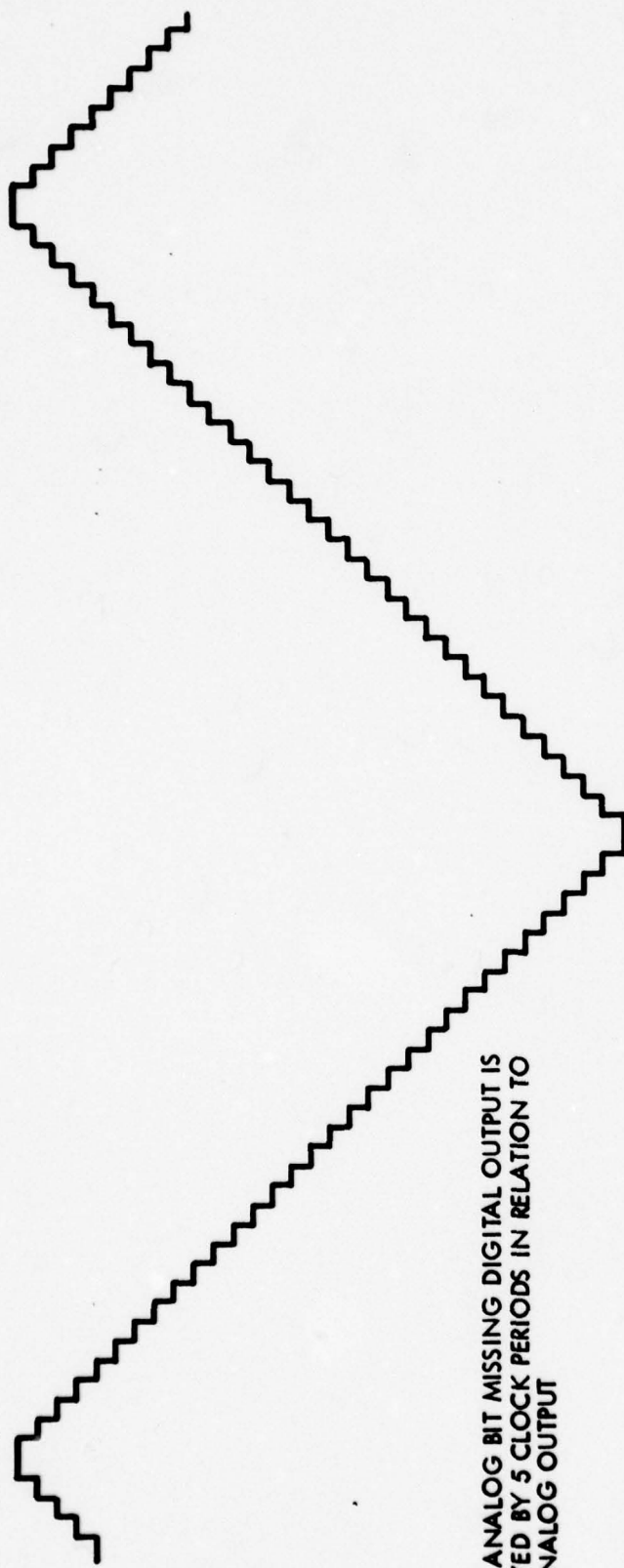


Figure 3-5. 32-D0C Probe Tester



32<sup>ND</sup> ANALOG BIT MISSING DIGITAL OUTPUT IS  
 DELAYED BY 5 CLOCK PERIODS IN RELATION TO  
 THE ANALOG OUTPUT

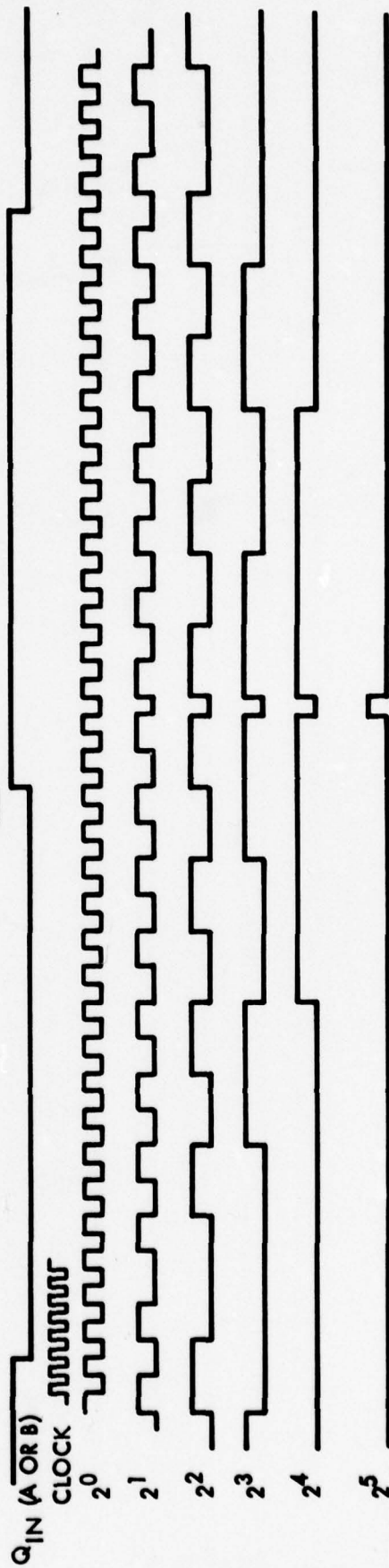


Figure 3-6. Timing Diagram





Figure 3-7. 32-D0C Expanded Analog Output

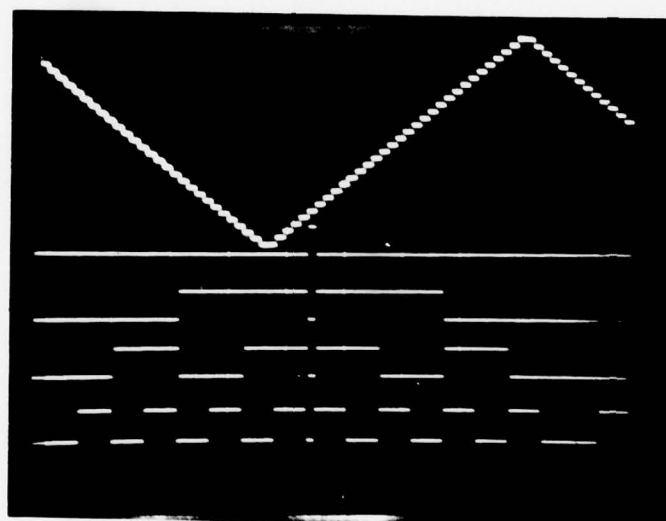


Figure 3-8. 32-DOC Analog-to-Digital Outputs

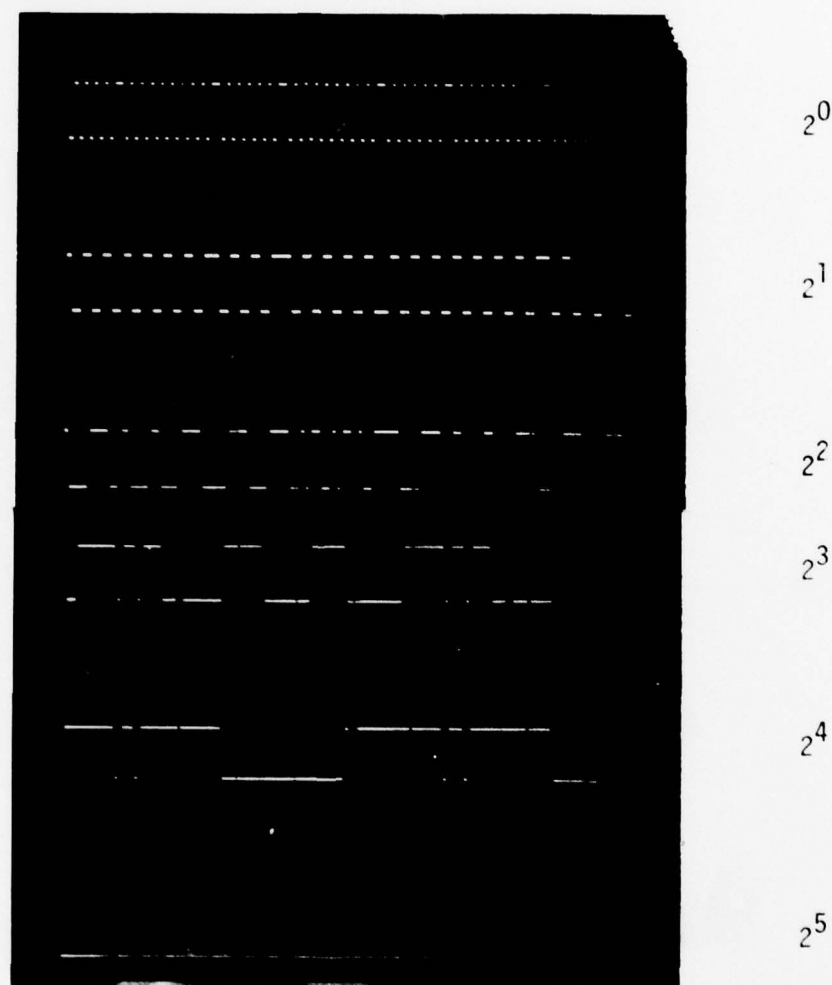


Figure 3-9. 32-D0C Digital Output

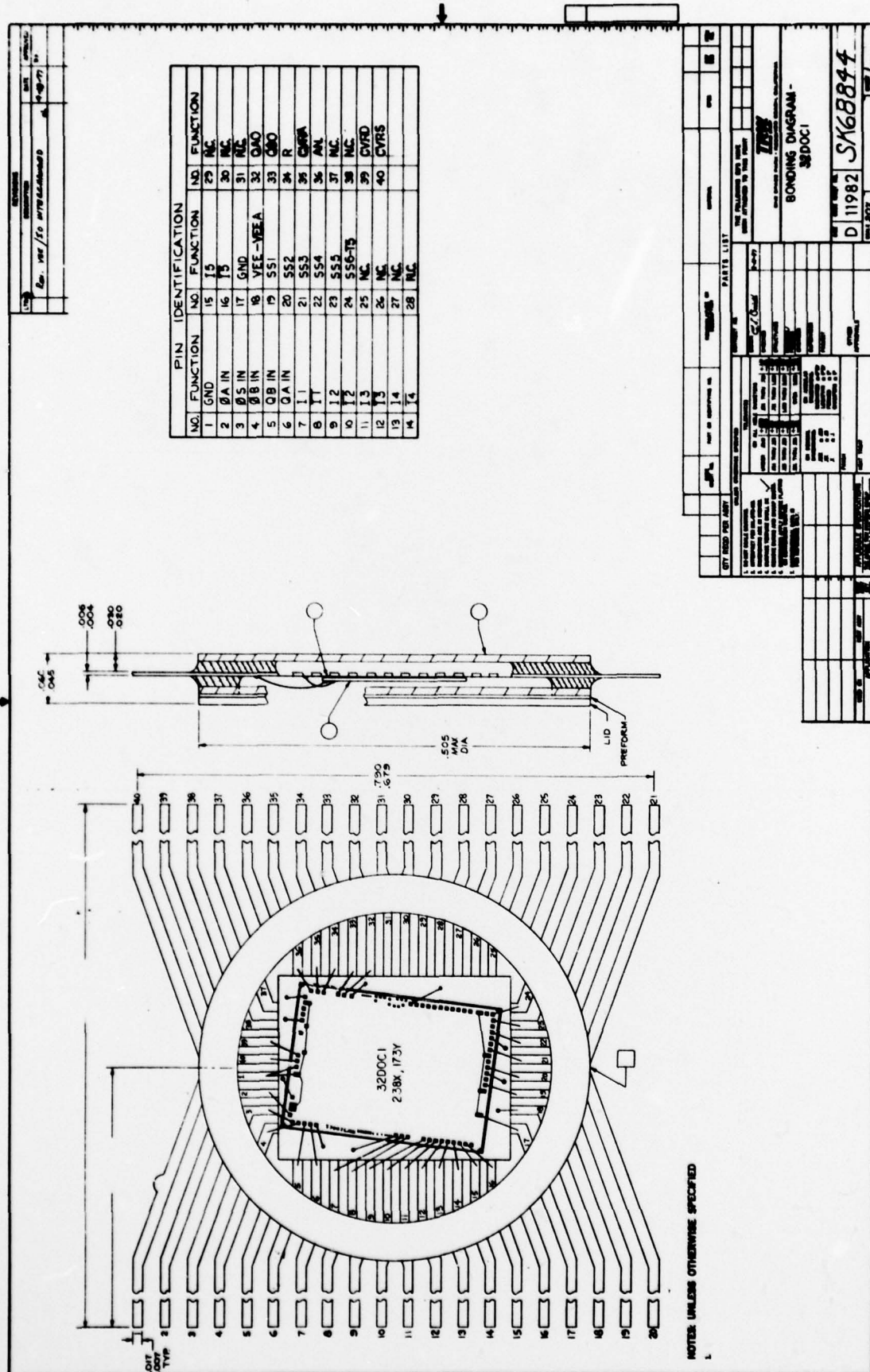


SR Input

SR Output

Figure 3-10. 32-DOC High Frequency Shift Register Output





#### 4. MONOLITHIC PROCESS

The OAT (Oxide Aligned Transistor) technology was developed by TRW to meet the demands of a high speed, low power bipolar LSI technology. The basic OAT process has been in use at TRW since 1971, and was used in this development to meet the demands of producing a low power, digital output correlator which operates at 150 MHz.

##### BASIC OAT PROCESS DESCRIPTION

The OAT process was designed to give microwave transistor devices at LSI yields. Since the small geometries needed for high frequency devices are opposed to the LSI complexity level objectives, special techniques are employed to achieve both simultaneously. These include the utilization of oxide wells for pseudo self-aligning and a polycrystalline arsenic emitter for higher yield of shallow base width transistors.

##### Oxide Well

In industry standard practice, each diffusion step is masked by a separate and independent photoresist-etch step. Each mask must be aligned very precisely to maintain minimum geometry construction. The limitations on minimum device dimensions are consequently a function of best routine alignment capability and worst-case mask distortions, such as run-out. OAT minimizes these problems by using a thick oxide well, as shown in Figure 4-1, to prealign subsequent diffusions. In the case shown, one mask prealigns three diffusions. Take for instance, the isolation diffusion: the isolation mask must be aligned anywhere within the region shown in Figure 4-2 to achieve "perfect alignment", etc., for the remaining two diffusions.

Two well structures are used in OAT. A deep well prealigns the isolation diffusion, deep collector N<sup>+</sup> diffusion, and the base diffusion. A shallow well prealigns the base contacts, the base enhancement diffusion, and the emitter. The oxide well structure, therefore, provides:

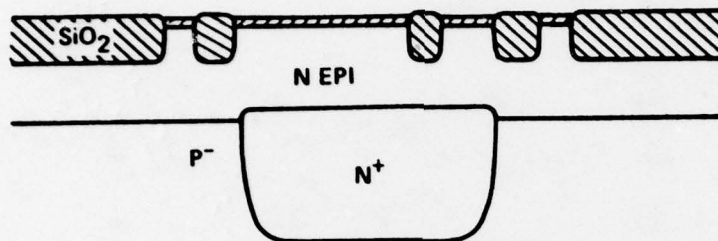


Figure 4-1. OAT Deep Well Structure

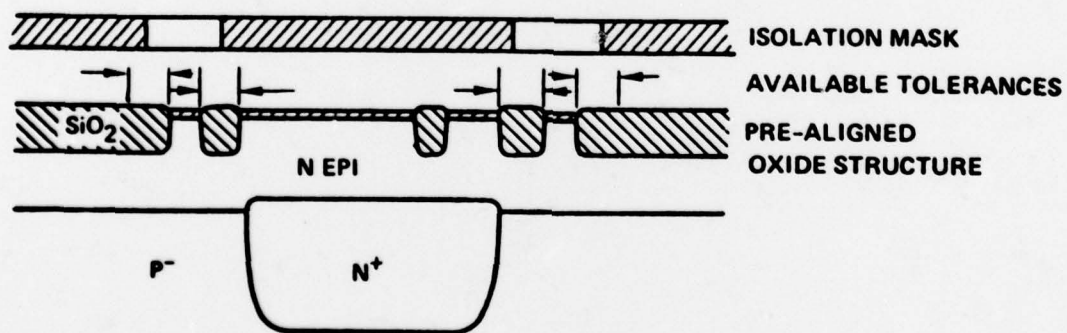


Figure 4-2. Alignment of the Isolation Mask



- Smaller device dimensions and lower junction capacitance due to limited lateral diffusion.
- Smaller device dimensions for a given mask and alignment capability (providing higher complexity LSI).
- Lower junction capacitance due to the oxide side walls.
- Smaller base-collector junction area since base contacts can be placed at the edge of the base.
- Improved radiation resistance due to the reduced PN junction area.

#### Polycrystalline Arsenic (PA) Emitter Source

The industry standard for the emitter-base structure of microwave devices is a washed emitter in which the emitter diffusion and the emitter contact occur in the same oxide cut, thus producing a minimum emitter-base junction area. The basic problem with this technique is that the etch dip which is needed to remove the  $\text{SiO}_2$ , formed during the emitter diffusion, also etches in a lateral direction. This enhances the incipient emitter-base short which exists when the contact metal is evaporated and alloyed, since this approach relies only on lateral diffusion of the emitter for protection and passivation of the emitter-base junction. This, in turn, reduces yield and high temperature reliability. This standard critical process step is eliminated in OAT by using an arsenic doped polycrystalline emitter doping source, as shown in Figure 4-3.

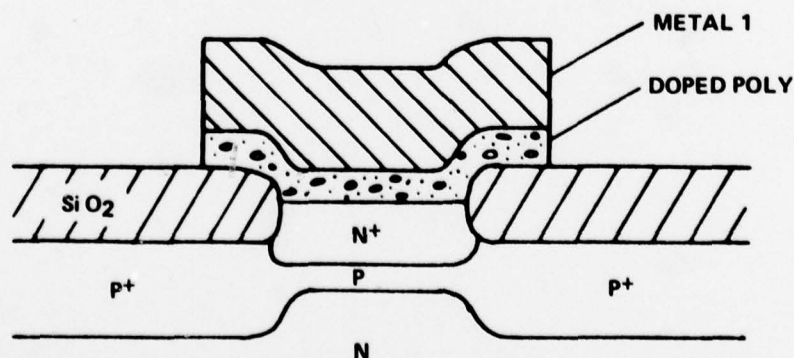


Figure 4-3. Polycrystalline Arsenic Emitter



A heavily arsenic doped polycrystalline film is deposited and patterned. The arsenic is driven in to form the emitter region. The doped poly is then covered with metal and forms the ohmic contact between the active emitter region and the metal contact. Thus, the metal system never makes contact with the silicon and is separated from it by the thickness of the poly. Emitter-base leakages and shorts are substantially reduced by this approach.

#### Semiconductor Processing

The processing sequence is listed in Table 4-1 and many of the steps are illustrated in Figure 4-4. The P-type substrate is oxidized, coated with photoresist, and the buried layer mask is exposed in the photoresist. The developed photoresist serves as a mask to allow the oxide to be etched away in the position of the N<sup>+</sup> buried layer diffusion; the diffusion is carried out using the remaining oxide as a mask to produce the structure shown in 4-4b. The oxide mask is then etched off, and an N-type epitaxial layer is grown. The next step in the OAT process is to grow a thin oxide, typically 200 Å, and deposit 1000 Å of silicon nitride on top of this. This is shown in Figure 4-4c.

In subsequent processing, use is made of the fact that silicon nitride and SiO<sub>2</sub> can be independently etched. Phosphoric acid, which is used to etch silicon nitride, attacks SiO<sub>2</sub> very slowly, and the buffered HF solution used to etch SiO<sub>2</sub> exhibits almost no attack on silicon nitride. Photoresist cannot be used directly to etch a pattern into silicon nitride, since it is attacked by hot phosphoric acid, but patterns can be etched indirectly by growing or depositing an oxide layer on the nitride, etching a pattern in the oxide with photoresist as a mask, then etching the nitride with the oxide pattern as a mask.

The oxide well pattern is etched into the silicon nitride layer with the above procedure, and then about 0.4μm of silicon is etched away using the nitride as a mask, as shown in Figure 4-4d. Next, about 1μm of oxide is grown. The growth of this oxide consumes about 0.45μm of silicon, with the result that the oxide is recessed into the silicon wafer to produce the deep oxide wells shown in Figure 4-4e. Next, the isolation mask is used to photoetch the silicon nitride from the region of the isolation diffusion (note that the alignment of this mask is not critical, as it can overlap

**Table 4-1. OAT Process Sequence**

OXIDIZE	
PR* BURIED LAYER	
BURIED LAYER DIFFUSION	(FIGURE 4-4B)
STRIP OXIDE	
EPI DEPOSITION	
NITRIDE DEPOSITION	(FIGURE 4-4C)
PR OXIDE WELL	
SILICON ETCH	(FIGURE 4-4D)
OXIDATION	(FIGURE 4-4E)
PR ISOLATION	
ISOLATION DIFFUSION	
OXIDATION	(FIGURE 4-4F)
PR DEEP COLLECTOR	
DEEP COLLECTOR DIFFUSION	(FIGURE 4-4G)
STRIP NITRIDE	
NITRIDE DEPOSITION	
PR CONTACT	(FIGURE 4-4H)
P+ BASE DIFFUSION	
OXIDATION	(FIGURE 4-4I)
STRIP NITRIDE	
IMPLANT ACTIVE BASE	
NITRIDE DEPOSITION	
BASE ANNEAL/DRIVE-IN	
PR EMITTER	(FIGURE 4-4J)
DOPED POLY DEPOSITION	
EMITTER DIFFUSION	
PR EMITTER POLY	(FIGURE 4-4K)
STRIP NITRIDE	(FIGURE 4-4L)

\* PR DENOTES THE ENTIRE PHOTOETCH PROCESS, INCLUDING COATING WITH PHOTORESIST, EXPOSURE OF THE MASK, DEVELOPMENT AND ETCHING.

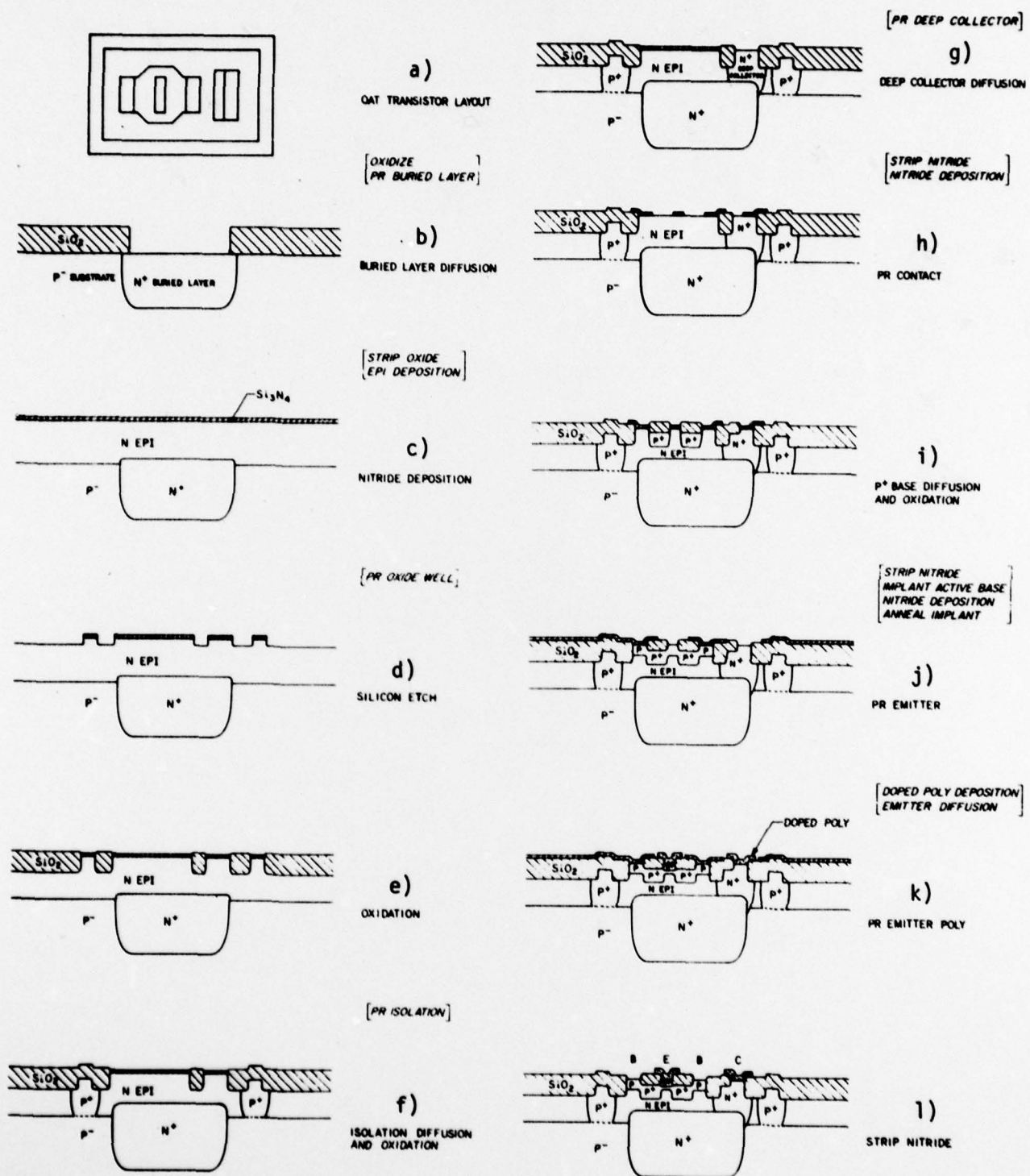


Figure 4-4. OAT Transistor Layout



onto the deep oxide well). Boron is diffused into the open region and then a fairly thick oxide is grown to seal off the isolation region. This is shown in Figure 4-4f. Next, the deep collector mask is used to photoetch the silicon nitride from the deep collector window, and phosphorous is diffused into the exposed silicon as shown in Figure 4-4g.

At this point in the process, the silicon nitride covering the base region is stripped off and a new silicon nitride layer deposited so that the entire wafer is covered with a uniform thickness of nitride. The contact mask is used to pattern this nitride layer as shown in Figure 4-4h. This leaves silicon nitride every place where contact will subsequently be made to the silicon. Boron is now diffused into the wafer. The boron concentration is lower than the phosphorous concentration in the deep collector region, so no junction is formed there, but a P<sup>+</sup> base region is formed in the epitaxial layer between the position of the base contacts and the emitter. The diffused resistors are also formed at this step. An oxide is then grown, giving the structure shown in Figure 4-4j. The nitride is then removed everywhere, and the active base dopant is ion implanted. This step provides a precise boron doping in the base contact regions. Another layer of nitride is deposited and the emitter mask is used to open the regions (emitter and collector) to which N type contacts will be made. The doped polycrystalline silicon layer is deposited and the emitter is diffused from the doped poly. A reversed polarity copy of the emitter mask is used to pattern the poly. It is left in place over the emitter and collector contacts and etched away everywhere else on the wafer. This is shown in Figure 4-4k. The semiconductor fabrication is completed by stripping off the remaining silicon nitride to open the base contacts as shown in Figure 4-4l. The wafer is now ready for surface processing, which will include multilayer metallization.

### Passive Devices

#### Metal-1

The first metal layer is a titanium-aluminum layer with 1500 Å and 5000 Å aluminum. This thickness is chosen to provide sufficient coverage of semiconductor device steps and to keep at a minimum step heights created by metal-1. The metals are serially evaporated using an electron



beam gun. Deposition pressure is approximately  $10^{-6}$  torr and substrate temperature is  $300^{\circ}\text{C}$ . Deposition rate is approximately  $50 \text{ \AA}$  per second.

#### Dielectric Deposition

The dielectric layer is deposited to a thickness of  $7000 \text{ \AA}$ , using standard silane vapor deposition techniques. Substrate temperature is  $400^{\circ}\text{C}$ , and the deposition rate is approximately  $200 \text{ \AA}$  per minute.

#### Metal-2

The second level of metal is an RF sputtered aluminum layer. The layer thickness is  $12,000 \text{ \AA}$ .

#### Passivation

The passivation layer is a  $3000 \text{ \AA}$  silane vapor deposited layer. See Table 4-2 for a summary of the surface process parameters.

Table 4-2. Summary of Surface Processing Parameters

<u>Process Step</u>	<u>Temperature</u>	<u>Pressure</u>	<u>Resistivity</u>	<u>Layer Thickness</u>
Metal-1	$300^{\circ}\text{C}$	$10^{-8}$ torr	$\sim 0.045 \text{ } \Omega/\square$	$6,500 \text{ \AA}$
Dielectric	$400^{\circ}\text{C}$	—	—	$7,000 \text{ \AA}$
Metal-2	$200^{\circ}\text{C}$	$6 \times 10^{-3}$ torr	$\sim 0.035 \text{ } \Omega/\square$	$12,000 \text{ \AA}$
Passivation	$400^{\circ}\text{C}$	—	—	$3,000 \text{ \AA}$

#### Device Characteristics

The physical dimensions and electrical characteristics for a typical OAT device are shown in Tables 4-3 and 4-4, respectively. The devices are scaled for peak operating performance depending on their use within the circuit. Figure 4-5 shows the  $f_T$  characteristics for a device optimized to operate in the 5-10 mA range.

Table 4-3. Physical Dimensions

Transistor:

Emitter Width	3 $\mu$ m
Base Contact Width	4 $\mu$ m
Metal-to-Metal Spacing	2 $\mu$ m
Minimum Transistor Size	44 $\mu$ m x 55 $\mu$ m

Table 4-4. Electrical Characteristics

Transistor:

$f_T = 4$ to 5 GHz	(CE cutoff frequency)
$C_{CO} = 0.14$ pf	(Zero voltage collector-base capacitance)
$C_{EO} = 0.08$ pf	(Zero voltage emitter-base capacitance)
$C_{CS} = 0.16$ pf at -3 volts	(Collector-substrate capacitance)
$I_C = 2$ mA	(Collector current)
$r'_C = 60$ ohms	(Collector series bulk resistance)

Resistor:

$R_S = 240$ ohms per square	(Sheet resistance)
-----------------------------	--------------------

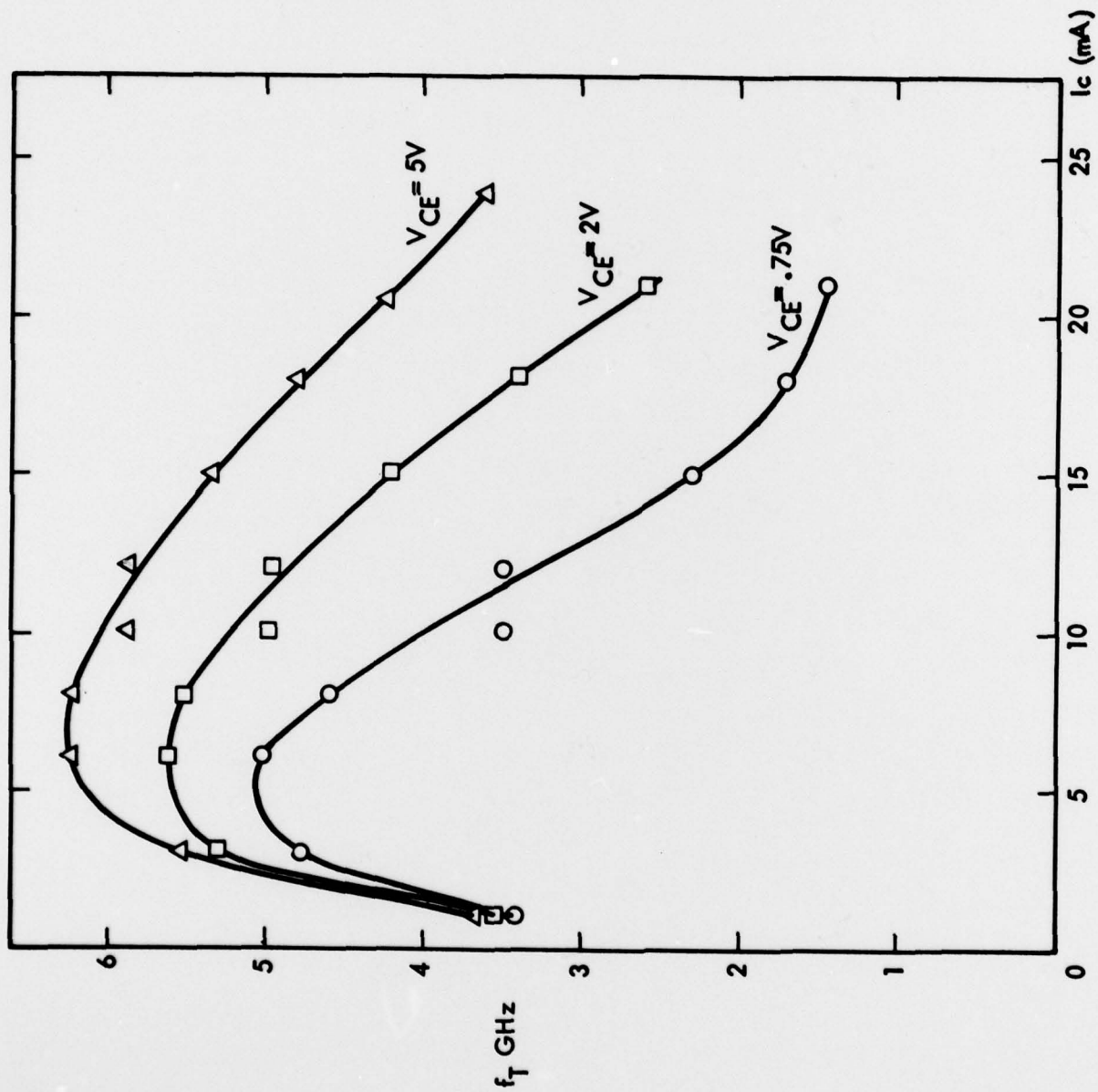


Figure 4-5. OAT Device  $f_T$  Characteristics

## 5. CONCLUSIONS

The primary objectives of developing an LSI high-speed, low-power digital output correlator have been met. The prime objective during this phase of the program was to develop a 32-bit digital parallel correlator with an analog summed output, and a digitally summed output.

Specifically, the program accomplished the following:

- Demonstration of a 32-bit digital output correlator capable of operating at clock rates greater than 125 MHz.
- A 32-bit digital output correlator which dissipates 800mW when biased for ECL compatibility.
- Composite delay x power product of approximately 1.0 picojoule/gate.
- Analog bit-to-bit accuracy of < 5%.

The main problem experienced, however, has been the high degree of circuit complexity and associated large die size. This has resulted in extremely low production yields.

Some recommendations for making this a more producible circuit are:

- Reduce the correlator length from 32 bits to 31 bits.
- Remove the option for providing low-level differential outputs, as well as ECL outputs.
- Provide either the skewed outputs or the de-skewed outputs, but not an option for both.

The current chip size is 238 mils by 173 mils. This results in very low yield for a process as complex as the OAT process. These recommended changes would eliminate 16 latches and five full adders, and would simplify the interconnect. This would reduce the chip size by approximately 20%, thus reducing chip power and enhancing producibility.